L Number	Hits	Search Text	DB	Time stamp
1	50	(("0245155") or ("5780406") or ("5705089") or ("5334332") or	USPAT	2003/01/15 13:01
		("5466389") or ("5308745") or ("4111767") or ("6503633") or		
		("5935920") or ("4617251") or ("6465368") or ("6495264") or		
		("5417877") or ("6495506") or ("Re30796") or ("5279771") or		
	1	("4239661") or ("5750482") or ("6339054") or ("5614027") or		
		("4786578") or ("4067690") or ("3954643") or ("6479374") or		
		("6110451") or ("6495573") or ("6500599") or ("6506937") or		
		("6489080") or ("6475700") or ("4824763") or ("6506537") or		
		("4549968") or ("6506318") or ("6492086") or ("6506759") or		
		("6482567") or ("6479211") or ("5646240") or ("6479039") or		
		("5744504") or ("6491970") or ("6482848") or ("6506419") or		
		("6498163") or ("6506738") or ("4350606") or ("6458849") or		
	5 0	("3582401") or ("3160539")).PN.	USPAT	2003/01/15 13:01
2	50	(("6245155") or ("5780406") or ("5705089") or ("5334332") or	USPAT	2003/01/13 13.01
		("5466389") or ("5308745") or ("4111767") or ("6503633") or ("5935920") or ("4617251") or ("6465368") or ("6495264") or		
		("5417877") or ("6495506") or ("Re30796") or ("5279771") or		
		("4239661") or ("5750482") or ("6339054") or ("5614027") or		
		("4786578") or ("4067690") or ("3954643") or ("6479374") or		
		("6110451") or ("6495573") or ("6500599") or ("6506937") or		
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		("4549968") or ("6506318") or ("6492086") or ("6506759") or		
		("6482567") or ("6479211") or ("5646240") or ("6479039") or		
		("5744504") or ("6491970") or ("6482848") or ("6506419") or		
		("6498163") or ("6506738") or ("4350606") or ("6458849") or		
		("3582401") or ("3160539")).PN.		
3	41	((("6245155") or ("5780406") or ("5705089") or ("5334332") or	USPAT;	2003/01/15 13:06
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		("5935920") or ("4617251") or ("6465368") or ("6495264") or	EPO; JPO;	
		("5417877") or ("6495506") or ("Re30796") or ("5279771") or	DERWENT;	
		("4239661") or ("5750482") or ("6339054") or ("5614027") or	IBM_TDB	
		("4786578") or ("4067690") or ("3954643") or ("6479374") or		
		("6110451") or ("6495573") or ("6500599") or ("6506937") or		
	1	("6489080") or ("6475700") or ("4824763") or ("6506537") or		
		("4549968") or ("6506318") or ("6492086") or ("6506759") or		
		("6482567") or ("6479211") or ("5646240") or ("6479039") or		
		("5744504") or ("6491970") or ("6482848") or ("6506419") or		
	,	("6498163") or ("6506738") or ("4350606") or ("6458849") or		
	ļ	("3582401") or ("3160539")).PN.) and (ammonium or fluoride or		
	_ !	sulfoxide or dmso or sulfone or chelating or chelate or lactate)	LICDAT.	2002/01/15 12:06
4	/	(((("6245155") or ("5780406") or ("5705089") or ("5334332") or	USPAT; US-PGPUB;	2003/01/15 13:06
		("5466389") or ("5308745") or ("4111767") or ("6503633") or ("5935920") or ("4617251") or ("6465368") or ("6495264") or	EPO; JPO;	
		("5417877") or ("6495506") or ("Re30796") or ("5279771") or	DERWENT;	
		("4239661") or ("5750482") or ("6339054") or ("5614027") or	IBM TDB	
		("4786578") or ("4067690") or ("3954643") or ("6479374") or	IBIM_IBB	
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		("4549968") or ("6506318") or ("6492086") or ("6506759") or		
		("6482567") or ("6479211") or ("5646240") or ("6479039") or		
		("5744504") or ("6491970") or ("6482848") or ("6506419") or		
		("6498163") or ("6506738") or ("4350606") or ("6458849") or		
	-	("3582401") or ("3160539")).PN.) and (ammonium or fluoride or		
		sulfoxide or dmso or sulfone or chelating or chelate or lactate)) and		
		(510/17\$.ccls.)		

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-----claim tree-----
1----8
+----13
+----12
+----11
+----10
+----9
+---7
 +----5
+----4
6
14----15----16----17
+---22
+----21
+----20
+----19
          +----18
23---24----25
+----31
+----30
+---29
    +----28
+----27
     +----26
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6245155
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Page 1

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  3582401
  3160539
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 134/2
  510/176
 134/3
 510/175
 134/40
  252/793
 134/38
  252/794
 134/41
  510/499
  510/212
 134/28
 134/902
  510/434
  430/329
 510/500
 134/13
  430/331
  510/202
 252/791
 510/505
  510/437
  510/407
  510/492
  528/21
  510/254
  510/245
 510/259
430/258
  428/447
 134/29
 427/132
 427/131
  427/130
 510/435
 510/257
 510/433
 134/12
 106/28712
 510/423
 430/330
 528/14
 528/34
 427/387
 134/34
 510/493
 134/2217
 134/42
 134/2219
 510/504
 525/446
 510/258
 134/2216
 510/108
 528/23
 134/36
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 134/254
  430/256
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Page 2

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427/289

427/420

528/39

510/272

510/501

106/28716

510/489

427/404

525/342

427/4071

430/326

510/255
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2-amino-2-ethoxy sulfone solvent amount water amount of water deionized water percent water weight percent water water hydrofluoric hydrogen ammonium fluoride ammonium hydrogen fluoride ammonium fluoride hydrogen fluoride sulfoxide dmso dimethylsulfoxide chelating co-solvent alkanolamine ethanolamine catechol gall ic propylene carbonate pyrrolidone ethyl lactate acetic acid methyl acetate methyl lactate hydrogen fluor ide ammonium hydrogen silicon oxide etching silicon substrate removing photoresist removing polyethylene glycol polyethylene N-methyl pyrrolidone pyrrolidone N-methyl propylene carbonate carbonate propylene gly col propylene ethyl lactate ethylene glycol ethyl acetate methyl lactate lactate methyl acetate acid methyl acetic acid acetic co-solvent hydroxide gallic acid chelating etching metal etching aqueous solution t riethanolamine diethanolamine formate monoethanolamine ethanol ammonium fluoride alkyl organic fluoride c

ompounds fluoride substrates etch residue residue etch cleaning stripping photo

resist photoresist stripping claimed sulfoxide corresponding sub sulfone independently dimethylsulfoxide hydroxylamine hydrazine diethylhydroxylamine choline tetramethylammonium monoisopropanolamine ratio solve nt/amine solution gallic catechol hydrogen tetrabutyl phosphonium silicon dicarbethoxyhydrazine coating c ompounds solvent amine ammonium aqueous metal oxide acid methyl acetate ethyl ethylene glycol diacetate m ethoxyethoxyethanol monolaurate appended claims organic amine ranges concentrations carboxylic ester groups ketone beneficial hydroxyl groups nitrogen carbonyl hydroxyl functional groups substituted chosen sever ingredients dissolution blend wetting balance fluoride salt benefits photoresist stripper rinse ambien timmersed agitation Stirring cleaning substrate derivatives hydroxides magnesium sodium potassium cleaning solution tartaric succinic oxalic malonic malic benzoic propionic formic organic acids hydrochloric acid hydrochloric phosphoric sulfuric silicone amphoteric nonionic anionic cation

ic cationic classified surfactant vinyl alcohol improves zinc nitrate zinc potassium nitrate polyols amid es deionized listed N-alkyl stated ratios dimethyl sulfoxide dimethyl desirably inhibit corrosion effecti veness glycols butyl acetate acetate ethyl discloses liquid phase ammonia evaporation extent contacting

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------ 6245155 classes: 1 134/3 1 134/12 1 134/2 1 134/2216 1 134/2217 1 134/2219 1 134/254 1 134/34 1 134/36 1 134/41 1 134/902 1 510/175 1 510/176 1 510/245 1 510/254 1 510/257 1 510/259 1 510/504 score: 965
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keywords: water; chelating; alkanolamine; catechol; substrate; removing photoresist; removing; ethylene glycol; hydroxide; chelating; etching; aqueous solution; alkyl; organic; fluoride; substrates; residue; etch; cleaning; photo resist; stripping; claimed; hydroxylamine; tetramethylammonium; solution; catechol; silicon; compounds; solvent; am ine; ammonium; aqueous; metal; oxide; acid; methyl; ethylene; glycol; hydroxyl; balance; photoresist stripper; rinse; derivatives; hydroxides; succinic; nonionic; cationic; surfactant; nitrate; deionized; discloses; contacting; elevated; consists; amines; photoresist stripping; inhibit; teaches; water-soluble; solubility; anionic; fluorine; plasm a ashing; spraying; published; quaternary ammonium; quaternary; ammonium hydroxide; ineffective; issued; Films; compositions used; rinsed; alkaline; aluminum alloys; frequently; acidic; tungsten; titanium; aluminum; involves; alkanolamines; oxygen plasma; oxygen;

the steps of: (i) contacting the **substrate** with a **cleaning** composition, and (ii) contacting the **substrate** with ozonated water. The preferred **cleaning** composition has a pH from 2 to 6 and comprises: (A) water; (B) at least one selected hydroxylammonium compound; and (C) at least one basic compound; and optionally (D) a **chelating** stabilizer; and optionally (E) a surfactant.

Inventors:

Leon; Vincent G. (Scottsdale, AZ); Honda; Kenji(Barrington, RI); Rothgery; Eugene F. (North Branford, CT)

Assignee:

Arch Specialty Chemicals, Inc. (Norwalk, CT)

Appl. No.: 055630 Filed:

> April 6, 1998 Current U.S. Class:

from about 2 to about 4.

- 3. The method of claim 1, wherein said **substrate** is contacted with said aqueous based **cleaning** composition by spraying said **substrate** with said **cleaning** composition.
- 4. The method of claim 1, wherein said **substrate** is rinsed with said ozonated water by spray rinsing.
- 5. The method of claim 1, further comprising a step of subjecting said
- **substrate** to dry **stripping**.

 6. The method of claim 1, further comprising a step of subjecting said **substrate** to **organic** wet **stripping**.
- 7. The method of claim 1, wherein said acidic hydroxylammonium compound is selected from the group consisting of hydroxylammonium salts of the formula:

n(NR.sub.1 R.sub.2 R.sub.3 OH).sup.+ (X.sup.-n)

wherein R.sub.1, R.sub.2 and R.sub.3 are individually selected from hydrogen, lower **alkyl** groups having 1 to 4 carbon atoms, lower alkoxy groups having 1 to 4 carbon atoms, hydroxyl and hydroxyl-substituted lower **alkyl** groups having 1 to 4 carbon a

onium phosphate, hydroxylammonium

oxalate, hydroxylammonium citrate, hydroxylammonium **fluoride** and hydroxylammonium chloride.

- 9. The method of claim 1, wherein the amount of hydroxylammonium compound is from about 1% to about 70% by weight of said **cleaning** composition.
- 10. The method of claim 1, wherein said amine is selected from the group consisting of hydroxylamine, **monoethanolamine**, **diethanolamine** **triethanolamine**, diethyleneglycolamine, and N-hydroxyethylpiperazine.
- 11. The method of claim 1, wherein said quaternary ammonium **hydroxide** is selected from the group consisting of tetramethylammonium **hydroxide** tetraethyl-ammonium **hydroxide**, trimethyl hydroxyethylammonium **hydroxide**, methyl tri (hydroxyethyl) ammonium **hydroxide**, tetra(hydroxyethyl)ammonium **hydroxide**, and benzyl trimethylammonium **hydroxide**.
- 12. The method of claim 1, wherein the amount of said basic compound in the **cleaning** composition is from about 0.01% to about 10% by w actants and anionic surfactants.
- 15. The method of claim 1, wherein said **cleaning** composition further comprises a corrosion inhibitor selected from the group consisting of:
- sugar alcohols and catechol. 16. The method of claim 5, wherein said dry **stripping** is a plasma oxygen
- 17. The method of claim 5, wherein said step of dry **stripping** is conducted prior to contacting said **substrate** with said aqueous-based **cleaning** composition.

Description

BACKGROUND OF THE INVENTION

1. Field of the Invention

This invention relates to a **cleaning** method for use in microelectronics manufacturing, and more particularly to a non-corrosive method for **removing photoresist** and plasma **etch **residue**s formed on wafer **substrates** after plasma **etching** of metal layers or oxide layers deposited on the **substrates**.

2. Brief Description of Art In the manufacture of microcircuits, positive **photoresist**s are used as an intermediate mask for transferring an original

----- 5780406 classes:1 510/175 1 134/13 1 134/2 1 134/3 1 134/38 1 134/40 1 134/41 1 134/42 1 510/176 1 510/437 score: 928

keywords: deionized water; water; chelating; alkanolamine; catechol; substrate; removing; ethylene glycol; hydrox ide; chelating; etching; aqueous solution; alkyl; organic; substrates; etch residue; residue; etch; cleaning; photor esist; stripping; claimed; hydroxylamine; tetramethylammonium; ratio; solution; catechol; compounds; solvent; amine; ammonium; aqueous; metal; oxide; acid; methyl; ethylene; glycol; nitrogen; hydroxyl; blend; balance; photoresist stripper; rinse; immersed; derivatives; hydroxides; cleaning solution; nonionic; cationic; surfactant; nitrate; deionized; discloses; contacting; consists; amines; photoresist stripping; adding; teaches; water-soluble; anionic; plasm a ashing; vapor; metal oxide; published; quaternary ammonium; quaternary; ammonium hydroxide; ineffective; Films; temperatures; alkaline; dissolving; acidic; tungsten; titanium; aluminum; involves; tetramethylammonium hydroxide; alkanolamines; oxygen plasma; oxygen;

d quaternary ammonium **hydroxide** radical; and n is the valence of X and is from 1 to 3; and (C) at least one basic compound selected from the group consisting of amines and quaternary ammonium **hydroxide**s.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS OF THE INVENTION It has been found that selective plasma **etching residue** removal with no *substrate** metal layer attack can be achieved by the combination of (1) adjusting a pH of the **cleaning** solution and (2) use of selected basic and acidic components. That is, the **cleaning** composition of the present invention comprises admixture of a basic component and an acidic component so as to set the pH of the solution in an acidic range of about 2 to about 6. The basic component used in this case is selected from amines and quaternary ammonium **hydroxide**s, while the acidic component is selected from hydroxylammonium salts which also contribute to enhance the removal of the plasma **etching** resi **ethanol**amine, **diethanolamine**, **triethanolamine**, diethyleneglycolamine, N-hydroxylethylpiperazine, and the Quaternary ammonium **hydroxide**s useful in the composition of the invention include tetraalkylammonium **hydroxide**s having **alkyl** groups of methyl, ethyl, propyl, butyl, hydroxyethyl, benzyl, and the combinations thereof (e.g., such as tetramethylammonium **hydroxide** (hereinafter referred to as TMAH), tetraethylammonium **hydroxide**, trimethyl hydroxyethylammonium **hydroxide**, methyl tri(hydroxyethyl)ammonium **hydroxide**, tetra(hydroxyethyl)ammonium **hydroxide**, benzyl trimethylammonium **hydroxide**, and the like). Additionally, a combination of ammonium **hydroxide** with one or more quaternary ammonium **hydroxide**s may also be used. Preferably, the basic compound is present in the composition of the invention in the range of about 0.01% to about 10% by weight, and the balance of the composition is water. A **chelating** stabilizer may be option ange of about 0.1 ppm to about 30 ppm by weight to a total weight of the **cleaning** composition of the present invention. The **cleaning** composition of the present invention can be used either in combination with the oxygen plasma ashing or with a conventional wet **photoresist stripping $\overset{\star}{*}$ solution. The $\overset{\star}{*}$ *cleaning** composition of this invention is not specifically designed to remove **photoresist** films from wafer **substrates**. Rather, the present **cleaning** composition is designed to remove plasma **etching residue**s after **removing photoresist**s by the dry or wet **stripping** methods. The **cleaning** composition of the invention can also be used to replace the **organic** solvent-based post-strip rinse because it is a non-corrosive and weakly acidic **aqueous solution** that will not harm the environment. Thus, the **cleaning** composition may be disposed of in a regular drain system for aqueous chemical wastes. The following Examples further illustrate the present

----- 5705089 classes:1 252/791 1 252/792 1 252/793 1 252/794 1 252/795 score: 906

keywords: water; hydrofluoric; chelating; substrate; removing; polyethylene glycol; polyethylene; propylene; acet ic; hydroxide; chelating; aqueous solution; alkyl; organic; substrates; cleaning; claimed; corresponding; choline; t

Page 5

etramethylammonium; solution; hydrogen; silicon; ammonium; aqueous; metal; oxide; acid; ethylene; glycol; carboxylic; carbonyl; substituted; wetting; tartaric; oxalic; hydrochloric acid; hydrochloric; phosphoric; sulfuric; nonionic; cationic; surfactant; improves; glycols; ammonia; novel; substances; adding; fluorinated; water-soluble organic; water-soluble; citric; anionic; ammonium salt; quaternary ammonium; quaternary; rinsed; improved cleaning; problem s; acidic; tetramethylammonium hydroxide;

dded additives shown in Table 5 in proportions shown in Table 5, respectively, at 85.degree. C. for 10 minutes for **cleaning**. Then, after rinsed with ultrapure water, the silicon **substrate** was examined by using a scanning electron microscope to check effect of **removing** silica particles on the silicon **substrate**. Results obtained are shown in Table 5.

Comparative Example 8
Similar procedures as in Examples 14 and 16 were repeated using lactic acid as an additive. Results obtained are shown in Table 5.

Comparative Example 9

Similar procedures as in Examples 14 and 16 were repeated using no additive. Result obtained are shown in Table 5.

TABLE5

Number of Particles on Surface of **substrate** (number/substrate) Removal

Amount Before After Ratio

Run No. Additive (ppm) **cleaning**

and

ultrapure water were mixed in proportions of 4:1:20 by weight, and additives shown in Table 6 were further added to the resulting mixture to prepare **cleaning** fluids. A silicon **substrate** of 3 inches in diameter of which native oxide was removed with diluted hydrofluoric acid treatment was dipped in the **cleaning** fluid thus obtained at 85.degree. C. for 10 minutes for **cleaning**. After rinsed with ultrapure water, this was examined for presence of residual additives based on absorptions of **organic** substances by using XPS analysis (X-ray Photo Sepctroscopy) and ATR-IR analysis (Attenuated Total Reflection Infrared Sepctroscopy). Results obtained are shown in Table 6.

Comparative Examples 10 and 11

Similar procedures as in Examples 17 and 19 were repeated using

polyethylene glycol **alkyl** ether (surfactant, Comparative Example 10) or

alkylbenzenesulfonic acid (surfactant, Comparative Example 11) as an
additive. Results obtain

5334332

classes: 1 510/175 1 134/2 1 134/40 1 510/108 1 510/245 1 510/254 1 510/434 1 510/489 1 510/492 1 510/505 score: 849

keywords: deionized water; water; chelating; alkanolamine; silicon oxide; substrate; removing; propylene glycol; propylene; ethylene glycol; hydroxide; chelating; etching; alkyl; organic; substrates; etch residue; residue; etch; cleaning; photoresist; stripping; corresponding; hydroxylamine; hydrazine; tetramethylammonium; ratio; solution; silicon; coating; compounds; solvent; ammonium; metal; oxide; acid; ethyl; ethylene; glycol; carboxylic; severe; balanc e; rinse; ambient; immersed; agitation; derivatives; potassium; deionized; effectiveness; extent; contacting; amines; photoresist stripping; metal ions; oxide etching; integrated circuit; synergistic; contamination; plasma ashin g; metal oxide; ammonium salt; ineffective; Films; polymers; bath; coatings; rinsed; temperatures; alkaline; chemica lly; polymeric; poor; tungsten; titanium; aluminum; involves; involving; tetramethylammonium hydroxide; alkanolami nes; oxygen plasma; oxygen; species; reacted; interaction; undesirable;

- onoamines. The

alkanol group of the amines preferably has from 1 to 5 carbon atoms.

Preferred alkanolamines suitable for use in the present invention can be represented by the chemical formula R.sub.1 R.sub.2 --N--CH.sub.2 CH.sub.2 --O--R.sub.3 wherein R.sub.1 and R.sub.2 can be H, CH.sub.3, CH.sub.3 CH.sub.2 or CH.sub.2 CH.sub.2 OH and R.sub.3 is CH.sub.2 CH.sub.2 OH.

Examples of suitable alkanolamines include **monoethanolamine**,

diethanolamine, **triethanolamine**, tertiarybutyldiethanolamine isopropanolamine, 2-amino-1-propanol, 3-amino-1-propanol, isobutanolamine, 2-amino-2-ethoxyethanol, and 2-amino-2-ethoxy-propanol.

Polar solvents suitable for use in the **stripping** composition of the present invention include **ethylene glycol**, **ethylene glycol alkyl** ether, diethylene glycol **alkyl** ether, triethylene glycol **alkyl** ether, **propylene glycol**, **propylene glycol alkyl** ether, dipropylene glycol **alkyl** ether, tripropylene

glycol **alkyl** ether, N-su like salts would not therefore be suitable for use based upon the understood mechanism of ionic contamination in a microcircuit as caused by **cleaning** and set forth above. As evident from the above formula, the carboxylic acid may be mono-, dior trisubstituted rather than tetra-substituted. A preferred **cleaning** composition of the present invention includes 30% by weight hydroxylamine, 25% by weight 2-amino-2-ethoxyethanol, 5% by weight 1,2-dihydroxybenzene and 50% by weight of water. The **stripping** compositions of the present composition are effective in **removing** a wide range of positive **photoresist**s but are particularly useful in **removing photoresist**s commonly consisting of an ortho-naphthoquinone diazide sulfonic acid ester or amide sensitizer with novolak-type binders or resins. Examples of commercially available **photoresist** compositions which the **stripping** compositions of the present invention effectively remove from a su ubstrates themselves include metal **substrates** such as aluminum, titanium/tungsten, aluminum/silicon, aluminum/silicon/copper; and **substrates** such as **silicon oxide**, silicon nitride, and gallium/arsenide; and plastic **substrates** such as polycarbonate. The **cleaning** compositions of the present invention are also effective in **removing** organometallic and metal oxide **residue** generated on the **substrate** of the **etching** equipment utilized. Examples of commercially available **etching** equipment include Lam Research, Tegal, Electrotech, Applied Material, Tokyo Electron, Hitachi and the like.

The method of **removing** a resist or other material from a **substrate** using the **stripping** compositions of the present invention involves contacting a **substrate** having a resist thereon with a **stripping** composition of the present invention for a time and at a temperature sufficient to remove the resist. The time and temperature are determined based on the particula

----- 5466389 classes:1 510/175 1 134/2 1 134/42 1 510/108 1 510/421 1 510/423 1 510/435 1 510/499 1 510/506 score: 836

keywords: deionized water; water; chelating; alkanolamine; acetic acid; silicon oxide; substrate; removing; acetic acid; acetic; hydroxide; chelating; etching; ethanol; alkyl; organic; substrates; etch residue; residue; etch; clea ning; photoresist; claimed; hydrazine; choline; solution; hydrogen; tetrabutyl; silicon; coating; compounds; ammoniu m; aqueous; metal; oxide; acid; acetate; glycol; beneficial; wetting; balance; benefits; hydroxides; cleaning solutio n; tartaric; oxalic; malonic; organic acids; hydrochloric acid; hydrochloric; nonionic; surfactant; potassium; nitr ate; deionized; listed; ammonia; contacting; amines; metal ions; inhibit; environmental; integrated circuit; silico n dioxide; dioxide; fluorinated; circi; contamination; plasma ashing; vapor; quaternary ammonium; quaternary; ethers; phase; ammonium hydroxide; tetraalkyl ammonium; nitric acid; nitric; dimensions; formulation; bath; rinsed; formulations; alkaline; dissolving; protective; wafer substrate; underlying metal; titanium; aluminum; involves; alk anolamines; undesirable;

Base Surfactant Concentration %	R.sub.z		
Concentration	(Angstroms)) pH	
tetraethylammonium		_	
none	5,000	13.1	
hydroxide (1.0)			
tetraethylammonium			
0.1	3,300	13.2	
hydroxide (1.0)			
tetraethylammonium			
0.1	<25	9.2	
hydroxide (1.0)			
choline (1.0)	4 200	12.0	
none	4,300	12.9	
choline (1.0)	250	13.1	
***	230	13.1	
choline (1.0) 0.1	<25	9.2	
2-aminoethanol (2.0)	a10,23	9.2	
none	16,000	11.9	
2-aminoethanol (2.0)	10,000	****	
0.1	1,200	12.0	
3.1	1,200		Page

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2-aminoethanol (2.0)
                                &1t;25
                                                9.2
                 0.1
    quanidine **carbonate**
                                            11.5
                                6.400
                 none
    (2.0)
    guani
     anium and then
     titanium nitride;
b. coating with a **silicon oxide** dielectric using chemical vapor deposition;
c. lithographic patterning of 0.5 to 1.0 microns vias using a **photoresist**
     material:
d. pattern transfer to the dielectric layer using reactive ion **etching**;
e. plasma ashing to remove most of the residual **photoresist**.
The resulting patterned wafers were contaminated with a considerable amount
     of residual ash that comprised a mixture of **organic** materials from the
     **photoresist** and inorganic materials from the underlying metal layer that
     had been partially exposed during step (d). The use of the hereinbefore
     described cleaner bath formulation as well as the following controlled pH
     alkaline **cleaning** solutions, all of which contained water, tetramethyl ammonium **hydroxide**, a nonionic surfactant (either 3,5-dimethylhexyne-3-ol
     or 1-butoxy-2-propanol), and a **chelating** agent (EDTA) and one of the
     following listed pH reducing components, rem
     oved this residual ash without
     damaging any silicon or metal features that were present.
```

pH Reducing Component рН 9.3-10.0 Ammonium acetate Ammonium acetate, ammonium **hydroxide**

9-10 **acetic acid**, ammonium **hydroxide** 9.5-10

acetic acid, 1-amino-2-propanol 9.5-10

acetic acid, hydrogen peroxide 9.3

Ammonium acetate, hydrogen peroxide 9.5

Ammonium acetate, nitric acid

9.5

Ammonium nitrate 8.9-10.0

Ammonium chloride, ammonium acetate, hydrogen peroxide 9.6-10.0

Ammonium chloride, ammonium acetate, ammonium

periodate 9-10

Ammonium chloride, ammonium acetate, ammonium 9.4-10.0

nitrate

------5308745

classes:1 430/329 1 430/256 1 430/260 1 430/311 1 430/325 1 430/326

score: 808

keywords: deionized water; water; hydrofluoric; sulfoxide; dmso; acetic acid; substrate; removing; polyethylene; c arbonate; acetic acid; acetic; aqueous solution; alkyl; organic; substrates; stripping photoresist; photoresist; s tripping; sulfoxide; hydroxylamine; monoisopropanolamine; solution; hydrogen; compounds; solvent; amine; ammonium; aqueous; metal; acid; methyl; ethyl; glycol; carboxylic; beneficial; substituted; photoresist stripper; rinse; deriv atives; hydroxides; organic acids; amides; deionized; listed; dimethyl sulfoxide; dimethyl; extent; amines; photore sist stripping; environmental; integrated circuit; adding; solubility; ethers; issued; Films; formulation; formula tions; alkaline; neutralized; titanium; aluminum; interaction; undesirable;

d or substantially eliminate metal corrosion on microcircuit **substrates** containing metals and coated with cross-linked or hardened **photoresist** resin. This invention also relates to a process for **stripping **photoresist** from cross-linked or hardened **substrates** employing alkaline-containing **photoresist stripping** compositions without incurring any substantial metal corrosion in microcircuit **substrates** containing metal and which provide greatly improved strip rates, with consequent decrease in strip time, compared to **stripping** compositions not containing the alkaline component. BACKGROUND OF THE INVENTION

An integral part of microelectronic fabrication is the use of **photoresist**s to transfer an image from a mask or reticle to the desired circuit layer.

After the desired image transfer has been achieved, the **photoresist** is removed by **stripping** before proceeding to some subsequent process step. Since about 1980, amides and mixtures of

----- 4111767 classes:1 205/717 score: 798

keywords: acetic acid; removing; polyethylene; acetic acid; acetic; hydroxide; aqueous solution; monoethanolamin e; organic; stripping; claimed; hydroxylamine; hydrazine; solution; coating; compounds; amine; ammonium; aqueous; met al; acid; ethyl; ethylene; immersed; tartaric; succinic; malic; organic acids; hydrochloric acid; hydrochloric; sulf uric; potassium; nitrate; substances; adding; water-soluble; citric acid; citric; nitric acid; nitric; bath; coating s; chemically; dissolving; substance; titanium; species;

 rophoretic coatings from stainless steel base materials almost without dissolving the base materials.

The object of this invention can be achieved by adding about 1 to about 100 g/l of at least one reducing compound selected from the group consisting of dimethylformamide, formaldehyde, thiosulfates, sulfites, hydrazine, hydroxylamine and dimethylaminoboron to a **stripping** composition consisting of a nitrate, a chlorine ion donor, and an amine compound and/or an **organic** acid having a buffering action, and adjusting the resulting bath to a pH of 6.0 to 9.5.

Stated more specifically, this invention provides an electrolytic **stripping** bath for **removing** metal coatings from stainless steel base materials comprising about 50 to about 500 g/l of a water-soluble nitrate, about 1 to about 200 g/l of a chlorine ion donor, about 0.5 to about 200 g/l of at least one of amine compounds and **organic** acids having a buffering action, and about 1

- lyl chloride and chloral hydrate. Of these examples, sodium chloride, ammonium chloride, chloral hydrate and ethylene chlorohydrin are preferable to use. The chlorine ion donor is used in an amount of about 1 to about 200 g/l, preferably about 5 to about 100 g/l.

amount of about 1 to about 200 g/l, preferably about 5 to about 100 g/l.

Examples of amine compounds and **organic** acids having a buffering action are ammonia, ethylenediamine, diaminopropane, diethylenetriamine, triethylenetetramine, tetraethylenepentamine, **monoethanolamine**, **diethanolamine**, **triethanolamine**, cyclohexylamine, aniline, toluidine, dimethylaniline, sulfanilic acid, urea, glycine, aspartic acid, alanine, glutamic acid, aminobenzoic acid, aminosuccinic acid, iminodiacetic acid, nitrilotriacetic acid, quadrol, ethylenediaminetetraacetic acid and like amine compounds, and **acetic acid**, succinic acid, itaconic acid, maleic acid, fumaric acid, phthalic acid, citric acid, malic acid, gluconic acid, glycolic acid, lactic acid, tartaric a

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classes:1 428/447 1 427/387 1 528/21 1 528/23 1 528/39 1 106/28712 1 106/28714 1 106/28716

score: 793

keywords: amount of water; water; hydrofluoric; gallic; substrate; polyethylene glycol; polyethylene; propylene glycol; propylene; ethylene glycol; acetic; hydroxide; etching; alkyl; organic; substrates; claimed; independently; tetramethylammonium; solution; gallic; hydrogen; silicon; coating; compounds; solvent; aqueous; oxide; acid; methyl; ethylene; glycol; ketone; nitrogen; ingredients; derivatives; succinic; oxalic; malonic; malic; benzoic; propionic; formic; organic acids; hydrochloric; phosphoric; sulfuric; silicone; amphoteric; nonionic; cationic; surfactant; potassium; dimethyl; ammonia; satisfactory; adding; citric; fluorine; vapor; published; ethers; hydrophilic; nitric; dielectric constant; Films; polymers; isopropanol; aromatic; protective; frequently; problems; poor; aluminum; tetramethylammonium hydroxide; oxygen; reacted;

 ulator to a value within that range produces the effect that the composition obtained has improved storage stability.

The pH regulator is used in an amount suitably selected so that the pH of the composition becomes a value within that range.

Organic Solvent (B)

The composition for film formation of the invention comprises the product of hydrolysis and condensation (A) usually dissolved or dispersed in an **organic** solvent (B).

organic solvent (B).

This **organic** solvent (B) may comprise at least one member selected from the group consisting of alcohol solvents, ketone solvents, amide solvents, ester solvents, and aprotic solvents.

report09903064.txt sec-butanol, t-butanol, n-pentanol, isopentanol, 2-methylbutanol, sec-butanol, t-butanol, n-pentanol, isopentanol, 2-methylbutanol, sec-pentanol, t-pentanol, 3-methoxybutanol, n-hexanol, 2-methylpentanol, sec-hexanol, 2-ethylbutanol, sec-heptanol, heptanol-3, n-oct ne glycol monopropyl ether, diethylene glycol monobutyl ether, diethylene glycol monohexyl ether, **propylene glycol** monomethyl ether, **propylene glycol** monopropyl ether, **propylene glycol** monobutyl ether, dipropylene glycol monomethyl ether, and dipropylene glycol monomethyl ether, dipropylene glycol monoethyl ether, and dipropylene glycol monopropyl Those alcohol solvents may be used alone or in combination of two or more thereof. Examples of the ketone solvents include acetone, methyl ethyl ketone, methyl n-propyl ketone, methyl n-butyl ketone, diethyl ketone, methyl isobutyl ketone, methyl n-pentyl ketone, ethyl n-butyl ketone, methyl n-hexyl ketone, diisobutyl ketone, trimethylnonanone, cyclohexanone, 2-hexanone, methylcyclohexanone, 2,4-pentanedione, acetonylacetone, acetophenone, and fenchone. Examples thereof further include .beta.-diketones such as acetylacetone, 2,4-hexanedione, 2,4-heptanedione,

3,5-heptanedione, 2 diethylacetamide, **N-methyl**pyrrolidone, N-formylmorpholine, N-formylpiperidine, N-formylpyrrolidine, N-acetylmorpholine, N-acetylpiperidine, and N-acetylpyrrolidine. Those amide solvents may be used alone or in combination of two or more

thereof.

.gamma.-butyrolactone, .gamma.-valerolactone, n-propyl acetate, isopropyl acetate, n-butyl acetate, isobutyl acetate, sec-butyl acetate, n-pentyl acetate, sec-pentyl acetate, 3-methoxybutyl acetate, methylpentyl acetate, 2-ethylbutyl acetate, 2-ethylhexyl acetate, benzyl acetate, cyclohexyl acetate, methylcyclohexyl acetate, n-nonyl acetate, methyl acetoacetate, ethyl acetoacetate, **ethylene glycol** monomethyl ether acetate, ethylene glycol monoethyl ether acetate, diethylene glycol monomethyl ether acetate, diethylene glycol monoethyl et

thylpiperazine, **N-methyl**imidazole, **N-methyl**-4-piperidone, **N-methyl**-2-piperidone, **N-methyl**-2-pyrrolidone,

1,3-dimethyl-2-imidazolidinone, and

1,3-dimethyltetrahydro-2(1H)-pyrimidinone.

Especially preferred of the **organic** solvents enumerated above are **organic** solvents represented by the following formula (5):

R.sup.10 O(CHCH.sub.3 CH.sub.2 O).sub.e R.sup.11 (5)

wherein R.sup.10 and R.sup.11 each independently represents a hydrogen atom or a monovalent **organic** group selected from the group consisting of **alkyl** groups having 1 to 4 carbon atoms and CH.sub.3 CO--; and e is an integer of 1 or 2.

Those **organic** solvents (B) may be used alone or as a mixture of two or more thereof.

In hydrolyzing and condensing the compounds (1) to (4) for preparing the composition for film formation of the invention, the same solvents as those enumerated above can be used.

An example of processes for producing the composition of the invention is as follows

classes:1 510/245 1 510/404 1 510/405 1 510/421 1 510/433 1 510/434 1 510/435 1 510/436 score: 788

keywords: deionized water; water; alkanolamine; carbonate; hydroxide; triethanolamine; alkyl; organic; cleaning; c laimed; corresponding; independently; solution; compounds; ammonium; aqueous; metal; acid; glycol; ranges; concentra tions; carboxylic; nitrogen; substituted; ingredients; wetting; balance; derivatives; cleaning solution; tartaric; amphoteric; nonionic; cationic; classified; surfactant; potassium; deionized; stated; ratios; discloses; substances ; water-soluble; solubility; citric; anionic; spraying; quaternary ammonium; quaternary; ethers; phase; polymers; cl eaning formulation; formulation; bath; temperatures; formulations; hydrocarbon; aromatic; alkaline; dissolving; im proved cleaning;acidic;neutralized;poor;

e used as powders, as pastes rich in active substances or as more or less highly concentrated aqueous concentrates. 2 to 10% by weight **aqueous solution**s are preferably used in the case of powders, 2 to 15% by weight **aqueous solution**s are preferably used in the case of pastes and 5 to 15% by weight aqueous solutions are preferably used in the case of liquid formulations. It is well known in the field of industrial cleaners that nonionic

surfactants can be combined with anionic surfactants. Accordingly, the present invention also encompasses processes in which, in addition to the formulations according to the invention, the aqueous **cleaning** solution additionally contains one or more anionic surfactants selected from at least one of the groups q) **alkyl** sulfates with a linear or branched C.sub.10-18 **alkyl** group, r) **alkyl** polyglycol ether sulfates with a linear or branched C.sub.10-18 **alkyl** group and 1 to 6 --CH.sub.2 --CH.sub.2 --

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classes:1 430/256 1 134/38 1 430/258 1 430/331 1 510/176 1 510/212 1 510/407 1 510/493 1 510/499 1 510/50

0 1 510/501 1 510/505

score: 761

keywords: deionized water; water; dmso; substrate; removing; ethanol; alkyl; organic; substrates; stripping; claime d; independently; tetramethylammonium; solution; silicon; coating; compounds; solvent; amine; aqueous; acid; acetate; glycol; ranges; ketone; ingredients; immersed; Stirring; deionized; N-alkyl; dimethyl; effectiveness; contacting; environmental; dioxide; bath; rinsed; temperatures; hydrocarbon; organic polymeric; polymeric; completion; problems; aluminum; involves;

ganic polymeric material can be immersed in a **stripping** bath or the **stripping** composition can be sprayed over the surface of the **organic** polymeric material, as will be apparent to those skilled in the art.

The **stripping** composition of the invention is effective in **removing** a wide variety of **organic** polymeric materials from **substrates**. Exemplificative **organic** polymeric materials include positive and negative resists, electron beam resists, x-ray resists, ion beam resists, as well as **organic** dielectric materials such as polymide resins, and so forth. Specific examples of **organic** polymeric materials which can be removed in the practice of the invention include positive resists containing phenol formaldehyde resins or poly(p-vinylphenol); negative resists containing cyclized polyisoprene or poly(p-vinylphenol); and polymethylmethacrylate-containing resists which are useful as electron beam or deep UV resists. In particularly

summarized in Table I below. In each case, with the exception of Example 16, either all or virtually all of the resist was removed with the **stripping** composition utilized. In Example 16, there was a 50% removal; however, when this Example was repeated by employing an immersion time of about 10-15 minutes, 100% removal was achieved.

In Table I, the following abbreviations are used:

For The Amine Compounds

2-(2-Aminoethoxy) **ethanol** AEE IBPA 3,3'-Iminobispropylamine **triethanolamine* TEA **monoethanolamine** MEA **diethanolamine** DEA 2-(2-Aminoethylamino) **ethanol** AEAE Triethylenetetramine TTN--(3-Aminopropyl) **diethanolamine** APDEA

For the **organic** Polar Solvents

NMP N--Methyl-2-Pyrr

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classes:1 438/780 1 428/414 1 438/781 1 528/10 1 528/12

score: 753

keywords: amount of water; water; hydrofluoric; chelating; gallic; substrate; removing; polyethylene; propylene g lycol; propylene; ethylene glycol; ethyl acetate; acetic; hydroxide; chelating; etching; aqueous solution; alkyl; o rganic; claimed; tetramethylammonium; solution; gallic; hydrogen; silicon; coating; compounds; solvent; ammonium; aq ueous; metal; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; ketone; nitrogen; Stirring; derivatives; tartaric; succinic; oxalic; malonic; malic; benzoic; propionic; formic; organic acid; hydrochloric; phosphoric; sulfuric; silicone; amphoteric; nonionic; cationic; potassium; dimethyl; butyl acetate; ammonia; evaporation; consists; amines; metal ions; adding; solubility; citric acid; citric; anionic; fluorine; vapor; hydrophilic; nitric acid; nitric; die lectric constant; Films; polymers; hydrocarbon; aromatic; alkaline; dissolving; acidic; poor; titanium; aluminum; te tramethylammonium hydroxide; oxygen; reacted;

```
xtraction into water or an acidic **aqueous solution**,
      followed by stirring, standing, and layer separation, is more preferable.
      When an acidic **aqueous solution** is used for the liquid-liquid extraction,
      it is desirable to repeat extraction several times using water to remove
      the acid.
As required, a solvent for forming coating films may be added to the
      polymer component solution thus obtained. Then, the residual water and
      specific **organic** solvent is removed from the polymer component solution by
      vacuum distillation or the like.
At least one solvent selected from the group consisting of alcohol
      solvents, ketone solvents, amide solvents, ester solvents, and
      non-protonic solvents can be used as the solvent for forming coating
      films.
The following solvents can be given as examples of alcohol solvents:
      monohydric alcohols such as methanol, **ethanol**, n-propanol, i-propanol,
     n-butanol, i-butanol, sec-butanol, t-butanol, n-pentanol, i-pen er, **ethylene glycol** monophenyl ether,
      **ethylene glycol** mono-2-ethylbutyl ether, diethylene glycol monomethyl
      ether, diethylene glycol monoethyl ether, diethylene glycol monopropyl
      ether, diethylene glycol monobutyl ether, diethylene glycol monobexyl
      ether, **propylene glycol** monomethyl ether, **propylene glycol** monoethyl ether, **propylene glycol** monopropyl ether, **propylene glycol** monobutyl
      ether, dipropylene glycol monomethyl ether, dipropylene glycol monoethyl ether, dipropylene glycol monopropyl ether, and the like.
These alcohol solvents may be used either individually or in combination of
      two or more.
Given as ketone solvents are acetone, methyl ethyl ketone, methyl n-propyl
     ketone, methyl n-butyl ketone, diethyl ketone, methyl i-butyl ketone,
     methyl n-pentyl ketone, ethyl n-butyl ketone, methyl n-hexyl ketone, di-i-butyl ketone, trimethylenonane, cyclohexanone, methyl cyclohexanone,
      2,4-pentane dione, acetonyl acetone, acetophe
      N-ethylformamide, N,N-diethylformamide, acetamide, **N-methyl**acetamide,
     N,N-dimethylacetamide, N-ethylacetamide, N,N-diethylacetamide,
**N-methyl**propioneamide, **N-methyl**pyrrolidone, N-formylmorpholine,
      N-formylpiperidine, N-formylpyrrolidine, N-acetylmorpholine,
N-acetylpiperidine, N-acetylpyrrolidine, and the like can be given. These amide solvents may be used either individually or in combination of
      two or more.
.gamma.-butyrolactone, .gamma.-valerolactone, n-propyl acetate, i-propyl
      acetate, n-butyl acetate, i-butyl acetate, sec-butyl acetate, n-pentyl
      acetate, sec-pentyl acetate, 3-methoxybutyl acetate, methylpentyl acetate,
      2-ethylbutyl acetate, 2-ethylhexyl acetate, benzyl acetate, cyclohexyl
      acetate, methylcyclohexyl acetate, n-nonyl acetate, methyl acetoacetate,
      ethyl acetoacetate, ethylene
      xide structure, polypropylene oxide structure,
      polytetramethylene oxide structure, polybutylene oxide structure, and the
      like can be given.
Specific examples of the compound having a polyalkylene oxide structure
      include ether compounds such as polyoxymethylene **alkyl** ether,
      polyoxyethylene **alkyl** ether, polyoxyethylene **alkyl**phenyl ether,
     polyoxyethylene sterol ether, polyoxyethylene lanolin derivatives, ethylene oxide derivatives of **alkyl**phenol formalin condensate,
      polyoxyethylene polyoxypropylene block copolymers, and polyoxyethylene
     polyoxypropylene **alkyl** ethers; ether-ester compounds such as polyoxyethylene glyceride, polyoxyethylene sorbitan fatty acid ester, polyoxyethylene sorbitol fatty acid ester, and polyoxyethylene fatty acid
      alkanolamide sulfate; and ester compounds such as **polyethylene** glycol
      fatty acid ester, **ethylene glycol** fatty acid ester, fatty acid
      monoglyceride, polyglycerol fatty acid ester, sorbitan fat
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----- 6495264 classes:1 428/447 1 525/342 1 525/446 1 528/14 1 528/21 1 528/34 score: 746

keywords: amount of water; water; hydrofluoric; gallic; acetic acid; substrate; polyethylene glycol; polyethylene e; propylene glycol; propylene; ethylene glycol; acetic acid; acetic; hydroxide; alkyl; organic; substrates; claime d; independently; tetramethylammonium; solution; gallic; hydrogen; silicon; coating; compounds; solvent; ammonium; a queous; metal; oxide; acid; methyl; ethylene; glycol; ketone; nitrogen; derivatives; hydroxides; succinic; oxalic; malonic; malic; benzoic; propionic; formic; organic acids; hydrochloric; phosphoric; sulfuric; silicone; amphote

ric; nonionic; cationic; surfactant; potassium; dimethyl; ammonia; amines; satisfactory; adding; fluorine; vapor; pub lished; ethers; hydrophilic; nitric acid; nitric; dielectric constant; Films; polymers; isopropanol; aromatic; prot ective; frequently; problems; poor; aluminum; tetramethylammonium hydroxide; oxygen; reacted;

ombination of two or more thereof. Examples of the pH regulator include inorganic acids and **organic** acids. Examples of the inorganic acids include hydrochloric acid, mitric acid, sulfuric acid, hydrofluoric acid, phosphoric acid, boric acid, and oxalic Examples of the **organic** acids include **acetic acid**, propionic acid, butanoic acid, pentanoic acid, hexanoic acid, heptanoic acid, octanoic acid, nonanoic acid, decanoic acid, oxalic acid, maleic acid, methylmalonic acid, adipic acid, sebacic acid, **gallic acid**, butyric acid, mellitic acid, arachidonic acid, shikimic acid, 2-ethylhexanoic acid, oleic acid, stearic acid, linoleic acid, linolenic acid, salicylic acid, benzoic acid, p-aminobenzoic acid, p-toluenesulfonic acid, benzenesulfonic acid, monochloroacetic acid, dichloroacetic acid, trichloroacetic acid, trifluoroacetic acid, formic acid, malonic acid, sulfonic acids, phthalic acid, fumaricacid, citricacid, tartaricacid 1 monoethyl ether, diethylene glycol monopropyl ether, diethylene glycol monobutyl ether, diethylene glycol monohexyl ether, **propylene glycol** monomethyl ether, **propylene glycol** monopropyl ether, **propylene glycol** monobutyl ether, dipropylene glycol monomethyl ether, **propylene glycol monomethyl ether, dipropylene glycol monomethyl ether, dipropylene glycol monoethyl ether, and dipropylene glycol monopropyl Those alcohol solvents may be used alone or in combination of two or more thereof. Examples of the ketone solvents include acetone, methyl ethyl ketone, methyl n-propyl ketone, methyl n-butyl ketone, diethyl ketone, methyl isobutyl ketone, methyl n-pentyl ketone, ethyl n-butyl ketone, methyl n-hexyl ketone, diisobutyl ketone, trimethylnonanone, cyclohexanone, 2-hexanone, methylcyclohexanone, 2,4-pentanedione, acetonylacetone, acetophenone, and fenchone. Examples thereof further include .beta.-diketones such as acetylacetone, 2,4-hexanedione, 2,4-heptan ide, N-ethylacetamide, N,N-diethylacetamide, **N-methyl**propionamide, **N-methyl**pyrrolidone, N-formylmorpholine, N-formylpiperidine, N-formylpyrrolidine, N-acetylmorpholine, N-acetylpiperidine, and N-acetylpyrrolidine. Those amide solvents may be used alone or in combination of two or more thereof. .gamma.-butyrolactone, .gamma.-valerolactone, n-propyl acetate, isopropyl acetate, n-butyl acetate, isobutyl acetate, sec-butyl acetate, n-pentyl acetate, sec-pentyl acetate, 3-methoxybutyl acetate, methylpentyl acetate, 2-ethylbutyl acetate, 2-ethylhexyl acetate, benzyl acetate, cyclohexyl acetate, methylcyclohexyl acetate, n-nonyl acetate, methyl acetoacetate, ethyl acetoacetate, **ethylene glycol** monomethyl ether acetate, ethylene glycol monoethyl ether acetate, diethylene glycol monomethyl ether acetate 5417877

classes:1 510/176 1 134/38 1 252/364 1 510/202 1 510/206 1 510/212 1 510/255 1 510/265 1 510/500

keywords: water; substrate; removing; polyethylene; N-methyl; propylene; ethylene glycol; etching; diethanolamine ;monoethanolamine;alkyl;organic;fluoride;substrates;etch;photoresist;stripping;claimed;solution;hydrogen; silicon; coating; compounds; solvent; amine; aqueous; metal; oxide; ethylene; glycol; carboxylic; nitrogen; hydroxyl; severe; ambient; nonionic; surfactant; amides; dimethyl; effectiveness; glycols; discloses; evaporation; contacting ;amines;substances;environmental;silicon dioxide;dioxide;synergistic;fluorine;vapor;ethers;ineffective;fo rmulation; coatings; temperatures; aromatic; chemically; dissolving; substance; polymeric; frequently; titanium; al uminum;

h is incorporated herein by reference.

The **stripping** compositions of this invention are especially useful and advantageous for numerous reasons among which may be mentioned the following. The **stripping** compositions are water miscible, non-corrosive, non-flammable and of low toxicity to humans and the environment. Because

of the low ambient vapor pressure of the compositions they evidence substantially less evaporation than prior compositions and are non-reactive and environmentally compatible. The **stripping** compositions may be recycled for multiple use or easily disposed of in an environmentally safe manner without the necessity for burdensome safety precautions. Likewise, a portion of the stripped coatings may be readily removed as solids and collected for easy disposal. The **stripping** compositions of this invention evidence higher **stripping** efficiency at lower temperatures for a wide variety of coatings and **substrates**.

orrosion prevention on two different metal **substrates**:

1) Pure 100% copper foil;

2) an Al/Cu (2%) metal alloy sputter deposited on top of a silicon

substrate.

The standard corrosion solvent used was of the following formulation:

Dimethylacetamide (DMA)

94% (w/w)

monoethanolamine (MEA) 6% (w/w)

Surfactant 0.2% added.

Previous tests with the following solvents were performed to assess corrosion propensity on pure copper **substrates**. Attack was assessed by a change in color of the solvent to blue or blue-green indicating formation of a stable complex of oxidized (i.e. corroded) copper. The solvents included:

- 1) DMA
- 2) DMF
- 3) Tetrahydrofurfuryl alcohol (THFA)
- 4) **propylene **carbonate**
- 5) **N-methyl**pyrrolidone (NMP)

None of the solvent is showed any effect on the Cu at all. Several amines (i.e., which are known to form stable complex

----- 6495506

classes:1 510/417 1 510/365 1 510/422 1 510/505 1 510/506 1 424/401 1 424/402 score: 724

keywords: amount of water; water; ethyl lactate; removing; polyethylene glycol; polyethylene; propylene glycol; propylene; ethyl lactate; ethylene glycol; lactate; alkyl; organic; residue; cleaning; independently; ratio; solution; hydrogen; compounds; solvent; amine; ammonium; aqueous; metal; oxide; acid; methyl; ethyl; ethylene; glycol; appended claims; organic amine; ranges; concentrations; carboxylic; ingredients; balance; benefits; magnesium; tartaric; phosphoric; sulfuric; amphoteric; nonionic; surfactant; N-alkyl; desirably; discloses; amines; novel; substances; en vironmental; satisfactory; teaches; water-soluble; solubility; citric acid; citric; anionic; European; published; ethers; phase; cleaning formulation; formulation; bath; temperatures; formulations; hydrocarbon; aromatic; alkaline; substance; polymeric; improved cleaning; acidic; aluminum; involves; reacted; undesirable;

r, mono, di, tributylene glycol monobutyl ether, mono, di, tributylene glycol monopentyl ether and mono, di, tributylene glycol monohexyl ether, **ethylene glycol** monoacetate and dipropylene glycol propionate. When these glycol type cosurfactants are at a concentration of about 0.5 to about 14 weight %, more preferably about 2.0 weight % to about 10 weight % in combination with a water insoluble **organic** ester or non water soluble material such as terpene, essential oils which is at a concentration of at least 0.5 weight %, more preferably 1.5 weight % to about 8 wt. % one can form a microemulsion composition.

While all of the aforementioned glycol ether compounds provide the described stability, the most preferred cosurfactant compounds of each type, is diethylene glycol monobutyl ether. Other suitable water soluble cosurfactants are water soluble esters such as **ethyl **lactate** and water soluble carbohydrates such as butyl gl roduct performance.

One such ingredient is an inorganic or **organic** salt of oxide of a multivalent metal cation, particularly Mg.sup.++. The metal salt or oxide provides several benefits including improved **cleaning** performance in dilute usage, particularly in soft water areas, and minimized amounts of perfume required to obtain the microemulsion state.

Magnesium sulfate, either anhydrous or hydrated (e.g., heptahydrate), is especially preferred as the magnesium salt. Good results also have been obtained with magnesium oxide, magnesium chloride, magnesium acetate, magnesium propionate and magnesium **hydroxide**. These magnesium salts can be

used with formulations at neutral or acidic pH since magnesium **hydroxide** will not precipitate at these pH levels.

Although magnesium is the preferred multivalent metal from which the salts (inclusive of the oxide and **hydroxide**) are formed, other polyvalent metal ions also can be used provided that th

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classes:1 134/2 1 134/19 1 148/243 1 252/180 1 252/390 1 252/394 1 422/16 1 510/245 1 510/247 1 510/253 score: 716

keywords: water; gallic; removing; carbonate; hydroxide; gallic acid; aqueous solution; organic; cleaning; claimed; corresponding; independently; solution; gallic; amine; ammonium; aqueous; metal; oxide; acid; methyl; ranges; concentrations; substituted; rinse; agitation; derivatives; magnesium; organic acids; effectiveness; ammonia; contacting; consists; amines; resistant; adding; solubility; citric; vapor; ammonium salt; ammonium hydroxide; rinsed; alkaline; acidic; neutralized;

- ich water is evaporated or heat transfer occurs, insoluble salts deposit on the surfaces to form scale. Usually the deposits consist of calcium and magnesium salts and result from the use of hard water, although sometimes the scale is based on elements other than calcium or magnesium.
- Common types of scale which deposit on metal surfaces include calcium sulfate (gypsum), calcium **carbonate** (limestone), complex calcium phosphate (hydroxy apatite) and calcium oxalate. In addition, scales containing a high iron content are also encountered.
- It has previously been known to use inorganic or **organic** acids to remove scale deposits from ferrous metal heat exchange equipment. After descaling, the equipment is normally drained of the acidic solvent, flushed with water and residual acid, neutralized with an alkaline solution, drained again and finally flushed with water.

 Alkali metal salts of **alkyl**enepolyamine polyacetic acids (hereafter APAPA)
- Alkali metal salts of **alkyl**enepolyamine polyacetic acids (hereafter APAPA),
 prototype ethylenediamine tetraacetic acid (EDTA), have also been used t
 - prototype ethylenediamine tetraacetic acid (EDTA), have also been used to remove scale from ferrous metal surfaces. They are ineffective, however, for **removing** iron oxide deposits at a pH above 8.
- When aqueous acids or **aqueous solution**s of alkali metal salts of APAPA having a pH below 8 are used, the resulting cleaned ferrous metal surfaces are prone to oxidation or rusting, and the build-up of scale is again under way.
- In accordance with the process of the present invention, scale and particularly iron oxide containing scale is removed from metal surfaces by a contacting treatment with an aqueous, alkaline, saline solution. As an essential feature, the solution employed contains at least one ammonium, amine or hydroxy **alkyl**amine salt of nitrilotriacetic acid (NTA), N-2-hydroxyethylamino diacetic acid (OHEtIDA), an **alkyl**enepolyamine polycarboxylic acid or mixture thereof. The contacting treatment is preferably carried
 - lamino-, methyl ethylamino-, propylamino-, isopropylamino-, isopropylamino-, trimethylamino-, the isomeric butylamino-, the isomeric amylamino- the corresponding mono(alkanol)-, di(alkanol)-, tri(alkanol)amino- particularly the mono(ethanol)amino-, di(ethanol)amino- and tri(ethanol)amino- salts.
- Representative of the ammoniated or aminated chelants set forth broadly above are those of ethylenediamine tetraacetic acid, diethylenetriamine pentaacetic acid, N-2-hydroxyethyl ethylenediamine triacetic acid, **propylene**-1,2-diamine tetraacetic acid, **propylene**-1,3-diamine tetraacetic acid, the isomeric butylenediamine tetraacetic acids, etc. When the chelants set forth above are ammoniated or aminated to a pH of 8 to 11, an average of one of the --CH.sub.2 CO.sub.2 H groups remains in the acid form since the bases used are not basic enough to form a fully substituted ammonium or amino salt of such chelants. In the formula given for such chelants,

5279771

classes:1 510/212 1 134/38 1 430/331 1 510/176 1 510/202 1 510/407 1 510/499 score: 714

keywords: deionized water; water; alkanolamine; silicon oxide; substrate; removing; propylene glycol; propylene; ethylene glycol; etching; alkyl; substrates; residue; photoresist; stripping; hydroxylamine; hydrazine; silicon; co ating; solvent; metal; oxide; acid; ethyl; ethylene; glycol; severe; rinse; immersed; agitation; derivatives; deionize d; effectiveness; contacting; amines; integrated circuits; integrated circuit; synergistic; ineffective; Films; po

lymers; bath; coatings; rinsed; temperatures; polymeric; involves; involving; alkanolamines; oxygen;

```
hydroxylamine. Further, the **stripping** composition can optionally contain
      one or more polar solvents. The addition of a polar solvent strengthens
      the effectiveness of the **stripping** composition. The **stripping** compositions
      allow for the clean removal of a resist from a **substrate**.
The **stripping** compositions of the present invention are particularly suitable for **removing** a **photoresist** material from a **substrate**, in
      particular, during the manufacture of a semiconductor integrated circuit
      without adversely affecting or hindering subsequent manufacturing
      operation or process steps.
Further, the **stripping** compositions of the present invention are suitable
      for **removing** cured polymer resists from a **substrate**, such as a partially
      or fully cured polyimide coating, and for **removing** organometallic polymers
formed on a **substrate** during plasma **etching** processes.

The method of **removing** a resist from a **substrate** using the **stripping**
      compositions o
      ub.1 and R.sub.2 can be H, CH.sub.3, CH.sub.3
CH.sub.2 or CH.sub.2 CH.sub.2 OH and R.sub.3 is CH.sub.2 CH.sub.2 OH.
Examples of suitable alkanolamines include **monoethanolamine**,
      **diethanolamine**, **triethanolamine**, tertiarybutyldiethanolamine isopropanolamine, 2-amino-1-propanol, 3-amino-1-propanol, isobutanolamine,
2-amino-(2-ethoxyethanol), and 2-amino(2-ethoxy)propanol.
Polar solvents suitable for use in the present invention include ethylene
      glycol, **ethylene glycol alkyl** ether, diethylene glycol **alkyl** ether,
      triethylene glycol **alkyl** ether, **propylene** glyol, **propylene glycol alkyl** ether, dipropylene glycol **alkyl** ether, tripropylene glycol **alkyl** ether,
      N-substituted **pyrrolidone**, ethylenediamine, and ethylenetriamine.
      Additional polar solvents as known in the art can also be used in the
      composition of the present invention.
The **stripping** compositions of the present composition are effective in **removing** a wide range of positive photoresi
                 4239661
classes:1 438/471 1 134/2 1 134/38 1 134/42 1 430/326 1 430/331 1 438/329 1 438/745 1 438/754 1 510/175 1
 510/372 1 510/373 1 510/421 1 510/434 1 510/504
```

keywords: deionized water; water; hydrofluoric; silicon oxide; substrate; removing; carbonate; acetic; hydroxide; etching; aqueous solution; triethanolamine; alkyl; organic; etch; cleaning; photoresist; choline; ratio; solution; hydrogen; silicon; coating; compounds; solvent; ammonium; aqueous; metal; oxide; acid; glycol; carboxylic; nitrogen; im mersed; hydrochloric acid; hydrochloric; phosphoric; sulfuric; nonionic; surfactant; potassium; deionized; ammonia; evaporation; extent; satisfactory; integrated circuit; adding; water-soluble; solubility; fluorine; phase; ammonium hydroxide; nitric acid; nitric; Films; waste; alkaline; dissolving; aluminum; oxygen; reacted;

rystal plane of <100>. This example gave the same results as in Example 6. Moreover, the N type silicon semiconductor **substrate** itself was little etched by the above-mentioned cholin solution containing H.sub.2 O.sub.2 and NH.sub.4 CN.

EXAMPLE 13

A **silicon oxide** film was formed on the surface of an N type silicon semiconductor **substrate**. A positive-working **photoresist** film was coated on the **silicon oxide** film, using a solution prepared by dissolving the raw material of a positive-working **photoresist** in an **organic** solvent. The **photoresist** film was heated about 20 minutes at 80.degree. C. to evaporate the **organic** solvent and to suppress fogging. Later, a light was projected through a prescribed photomask aligned with the **photoresist**. Those portions of the **photoresist** on which a light was projected were etched by a 2.44% aqueous choline solution while those portions of the **photoresist** on which a light was not projected

----- 5750482 classes:1 510/182 1 510/427 1 510/428 1 510/429 1 510/505 1 510/506 score: 672

keywords: deionized water; water; chelating; acetic acid; carbonate; propylene glycol; propylene; ethylene glycol; acetic acid; acetic; hydroxide; chelating; monoethanolamine; alkyl; organic; cleaning; claimed; solvent; amine; am monium; aqueous; metal; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; concentrations; severe; ingredients; we tting; benefits; Stirring; succinic; propionic; organic acids; hydrochloric; phosphoric; sulfuric; amphoteric; noni

onic; surfactant; potassium; amides; deionized; dimethyl; effectiveness; glycols; discloses; ammonia; elevated; cons ists; environmental; water-soluble; citric; anionic; European; quaternary ammonium; quaternary; phase; ammonium hy droxide; isopropanol; temperatures; hydrocarbon; aromatic; alkaline; acidic; aluminum;

```
1.0
    Potassium iodide
                       0.003
                       < &lt; Q.S. 100% &gt; &gt;
    Water
The Composition Q was tested as in Example 1 (but with 20 judges) against
     the Procter and Gamble product CINCH, which contains 3% **propylene glycol**
     monobutyl, ether and 7% isopropyl alcohol. CINCH also contained an
     alkalizing agent which is **monoethanolamine** and a surfactant.
The test results indicated that Composition Q was superior to CINCH,
     notwithstanding the very high solvent contained in that commercial product
     (66 wins, 14 losses, 1.03 average **cleaning** score).
EXAMPLE 10
The compositions in the table which follows are illustrative of the present
     invention.
                   CONCENTRATION (Wt. %)
                   RS T U V W X Y Z
    Ingredient
              -- 0.1
                                 -- -- 0.15
    Sodium dodecyl benzene sulfonate
                   0.1
                     0.1
                         -- 0.08
                              0.2
                                 0.15
                                    0.25
    Nonoxynol-5
                     0.05
                         - 0.05
                               -- -- 0.10
                                          0.1
    Polyacrylic acid
                                 -- 0.02
                     0.02 --
                                       -- 0.05
    (MW = 3000)
    Fluorosurfactant
                     0.01
                         - 0.01
                               -- 0.01
                                     -- 0.02
    **acetic acid**
                     -- 0.15
```

----- 6339054 classes:1 510/241 1 510/495 1 510/504 score: 647

0.1176

Ammonia (29.4% active)

0.05

Fluorad FC 129

keywords: water; hydrofluoric; chelating; gallic; acetic acid; substrate; removing; carbonate; propylene glycol; propylene; ethylene glycol; acetic acid; acetic; hydroxide; gallic acid; chelating; aqueous solution; ethanol; alky l; organic; substrates; residue; cleaning; independently; ratio; solution; gallic; compounds; solvent; amine; ammoniu m; aqueous; metal; oxide; acid; methyl; ethylene; glycol; ranges; concentrations; carboxylic; beneficial; substituted; chosen; ingredients; wetting; balance; benefits; rinse; hydroxides; cleaning solution; tartaric; succinic; oxalic; malic; formic; organic acids; phosphoric; amphoteric; nonionic; cationic; surfactant; improves; potassium; listed; stated; dimethyl; desirably; extent; amines; metal ions; novel; satisfactory; recognized; water-soluble; citric acid; citric; anionic; spraying; cleaning metal; carboxylate; quaternary ammonium; quaternary; phase; Films; formulation; waste; rinsed; temperatures; formulations; aromatic; alkaline; been removed; acidic; aluminum; species; reacted; undesirable;

trates, leaving water droplets. The **substrates** look .about.95% dry in 2.25 mins. They feel dry to the 20 PPM Half of the window fogs. No visible change on the **substrate**. The window fogs from the top down and has droplet and 100 PPM water streams. Stable foam of 1.5". Foam droplets or bubbles remain on the surface of the 200 PPM **substrates**. Foam level is 3". Water sheets rapidly. It took 1.5 mins drying time to reach the .about.95% dry surface. 300 PPM 5-6 inches of foam. Signs of film on the **substrates**. 6 inches of foam. Test was aborted at this point. While 500 PPM **cleaning** the machine a yellowish grease scum was detected on the back wall of the machine. USE SOLUTION PH STUDY pH of Vo aqueous) 3.50 Oxalic Acid dihydrate 99% Videt RFG Non-ionic Surfactant 6.00 Linear Dodecyl Benzene Sulfonic Acid 97% 6.00 Nonylphenol Ethoxylate 9.5 Mole 2.50 7.50 Dehypon .TM. LS-54 non-ionic surfactant GlenSurf .TM. 42 cationic surfactant 1.25 **propylene glycol** Monomethyl Ether 6.00 Aliphatic Hydrocarbon 2.00 100% TOTAL This composition has found particular utility for touchless and friction-type car and truck washes, wheel **cleaning** and brightening processes in car washes. Carbon soil film removal in truck washing, rust stain removal in truck washing. The function of the oxalic acid (as an example of the **organic** acid) and the phosphoric acid (as an example of the inorganic acid) have been noted as follows:

1) Phosphoric acid alone -- No aluminum brightening

2) Oxalic acid alone--Some

classes:1 134/2 1 134/29 1 134/40 1 510/255 1 510/258 1 510/259 1 510/272 1 510/423 1 510/433 1 510/434 1 510/435 1 510/437 1 510/492 1 510/500 1 510/505 score: 640

keywords: deionized water; water; alkanolamine; ethanolamine; pyrrolidone; substrate; removing; pyrrolidone; carb onate; propylene; hydroxide; aqueous solution; alkyl; organic; substrates; cleaning; claimed; corresponding; ratio; solution; hydrogen; compounds; solvent; amine; ammonium; aqueous; metal; oxide; acid; ethylene; concentrations; carbo xylic;nitrogen;ingredients;balance;immersed;agitation;derivatives;magnesium;cleaning solution;nonionic;cl assified; surfactant; zinc; potassium; amides; deionized; N-alkyl; ratios; effectiveness; discloses; contacting; ele vated; consists; amines; metal ions; inhibit; novel; environmental; recognized; water-soluble; contamination; anion ic; cleaning metal; ethers; ketones; polymers; bath; waste; toxic; rinsed; formulations; hydrocarbon; alkaline; probl ems; aluminum; involves; species; undesirable;

osphate esters of alkoxylated alcohols and sodium, potassium and ammonium salts of the **alkyl** sarcosinates. The hydrotropes are useful in maintaining the **organic** materials including the surfactant readily dispersed in the aqueous **cleaning** solution and, in particular, in an aqueous concentrate which is an especially preferred form of packaging the compositions of the invention and allow the user of the compositions to accurately provide the desired amount of **cleaning** composition into the aqueous wash solution. A particularly preferred hydrotrope is one that does not foam. Among the most useful of such hydrotropes are those which comprise the alkali metal salts of intermediate chain length linear **alkyl** monocarboxylic fatty acids, i.e., C.sub.7 -C.sub.13. Particularly preferred are the alkali metal octanoates and nonanoates.

The metal **cleaning** compositions of this invention comprise from about 20 to 80 weight percent based on

ution. It is to be understood that higher levels of the magnesium ion can be included in the **aqueous solution** but for the most part, higher levels than that described are not believed to add significantly to the anticorrosive effect. The zinc ion is effective at concentrations between

1 and 1,000 ppm with respect to the aqueous **cleaning** solution. Again,
higher levels of the zinc ion can be used but such higher levels are not
believed to increase the anticorrosive effect. When used alone, the zinc
ion is preferably utilized in concentrations of 25 to 100 ppm in the
 cleaning solution. When used with magnesium, the zinc ion levels are
 preferably from about 2 to 25 ppm based on the **cleaning** solution.
The aqueous metal **cleaning** solutions of the present invention are useful in
 removing a variety of contaminants from metal **substrates** as previously
 described. A useful method of **cleaning** such metal parts is in a parts
 washer. In parts

----- 4786578 classes:1 430/256 1 134/38 1 252/8 1 430/326 1 430/329 1 430/331 score: 632

keywords: water; substrate; removing photoresist; removing; etching; aqueous solution; triethanolamine; diethano lamine; alkyl; organic; substrates; residue; photoresist; stripping; claimed; ratio; solution; silicon; coating; solvent; aqueous; oxide; acid; ethylene; beneficial; dissolution; rinse; immersed; nonionic; surfactant; deionized; extent; amines; photoresist stripping; integrated circuits; water-soluble; solubility; contamination; bath; coatings; temperatures;

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United States Patent: 4,786,578
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FULL TEXT FORMAT -->
igadn3
&nbsp:
( lof1)
United States Patent
       4,786,578
Neisius
, &nbsp et al.
November 22, 1988
Agent and method for the removal of **photoresist** and stripper **residue**s
    from semiconductor **substrates**
Abstract
Photoresist and stripper **residue**s can be rapidly and completely removed
     from semiconductor **substrates** after the **stripping** process with an aqueous
     post-rinsing agent which contains a nonionogenic surfactant and an **organic**
     base.
  Inventors:
  Neisius; Karl H. (Darmstadt, DE);
Litters; Alois (Lampertheim Hofheim, DE)
  Assignee:
 Merck Patent Gesellschaft mit beschrankter Haftung(Darmstadt, DE)
Appl. No.:
077970
 Filed:
  July 20, 1987
  Foreign Application Priority Data
  Jan 19, 1985[DE] 3501675
 Current U.S. Class:
  430/256; 134/38; 252/8; 430/326; 430/329; 430/331
  Intern'l Class:
  G03C 011/12
 Field of Search:
 430/326,329,3
    ein the **organic** base is **ethanol**amine, **diethanolamine** or
     **triethanolamine**.
6. A method of claim 5, wherein the **photoresist residue** is a positive
     **photoresist**.
```

- 7. A method of completely **removing photoresist** structures and **residue**s from a **substrate** which has been subjected to **photoresist** imaging, comprising treating the **substrate** with a **photoresist** stripper, **removing** the **substrate** from the stripper, and treating the **substrate** with a post-rinsing agent comprising effective amounts of a nonionic surfactant and an **organic** base in **aqueous solution**, said **organic** base being water soluble to a degree whereby it will form a water soluble salt with **alkyl**benzenesulfonic acids when the agent is contacted therewith.
- 8. A combination of (a) a **substrate** which has been subjected to **photoresist** **stripping** with a **photoresist stripping** agent and removed from said **photoresist stripping** agent and has resultant **photoresist** or stripper **residue** thereon, a

4067690

classes:1 422/16 1 252/387 1 252/392

score: 629

keywords: water; N-methyl; carbonate; hydroxide; alkyl; claimed; hydroxylamine; hydrazine; ratio; solution; compoun ds; aqueous; metal; acid; methyl; severe; derivatives; hydrochloric; sulfuric; effectiveness; ammonia; elevated; cons ists; novel; dioxide; adding; water-soluble; nitric acid; nitric; toxic; temperatures; alkaline; acidic; involves; ox

EHA) was

determined at 68.degree. F. without a catalyst and with a catalyst copper **carbonate** in a ratio of DEHA to catalyst of 100:1 parts by weight. A dosage of 10% excess DEHA was used based on 1 ppm of DEHA is required per 1 ppm of dissolved oxygen. The pH of the testing solution was adjusted by using dilute sodium **hydroxide** solution. The following results were recorded:

TABLE 6

N, N-DIETHYLHYDROXYLAMINE AND OXYGEN REACTION RATE AT 68.degree. F. AND pH 11 Time in DISSOLVED OXYGEN, mg/liter Minutes No Catalyst Copper **carbonate** as Catalyst

0	8.60	8.70	
5	7.30	3.70	
10	6.65	2.50	
15	5.90	1.95	
20	5.75	1.40	
30	5.10	0.40	
60	4.60	0.10	

EXAMPLE 7

The oxygen scavenging activit

e of hydroxylammonium acid

sulfate and N, N-diethylhydroxylamine over hydrazine is evident. The following compounds according to this invention show similar unexpected oxygen scavenging activities when tested by the procedure described in Example 1.

Example No.

8 Hydroxylamine phosphate

9 N-Ethylhydroxylamine

- 10 N, N-Dimethylhydroxylamine
- 11 O-Methylhydroxylamine
- 12 O-Hexylhydroxylamine
- 13 N-Heptylhydroxylamine
- 14 N, N-Dipropylhydroxylamine
- 15 O-Methyl N, N-diethylhydroxylamine
- 16 N-Octylhydroxylamine
- 17 O-Ethyl N, N-dimethylhydroxylamine
- 18 N, N-Diethylhydroxylamine hydrochloride
- 19 **N-methyl** N-ethylhydroxylamine
- 20 O-Methylhydroxylamine phosphate
- 21 N-Butylhydroxylamine
- 22 N-Benzylhydroxylamine (.beta.-Benzylhydroxylamine)
- 23 O-Benzylhydroxylamine (.alpha.-Benzylhydroxylamine)
- 24 N, N-Diethylhydroxylamine acetate

The presently used hydroxylamines may be catalyzed using any of a number of well known catalyst used in sodium sulfite or hydrazine boiler water

classes:1 510/305 1 510/283 1 510/292 1 510/306 1 510/307 1 510/308 1 510/316 1 510/324 1 510/351 1 510/3
52 1 510/355 1 516/126
score: 627
keywords: water;propylene;acetic;aqueous solution;alkyl;organic;residue;corresponding;sulfone;ratio;solution;hydrogen;compounds;ammonium;aqueous;metal;oxide;acid;methyl;ethylene;concentrations;carboxylic;nitrogen;substituted;ingredients;derivatives;magnesium;tartaric;sulfuric;cationic;potassium;amides;stated;dimethyl;extent;consists;amines;substances;water-soluble;citric acid;citric;anionic;published;ethers;bath;waste;temperatures;formulations;aromatic;alkaline;substance;oxygen;

acid, 12% by weight of a C.sub.20 fatty acid, and 48% by weight of a C.sub.22 fatty acid (iodine value 4) (Soap B), respectively. "PEM" is the sodium salt prepared from 1:1 copolymerizate of ethylene and maleic acid anhydride with a specific viscosity 0.29 (1% by weight dissolved in dimethyl formamide at room temperature). "PPM" is the sodium salt prepared from a 1:1 copolymerizate of **propylene** and maleic acid anhydride with a specific viscosity 0.30 (1% by weight dissolved in dimethyl formamide at room temperature). "ABS" is the salt of an **alkyl**benzenesulfonic acid with 10 to 15, substantially 11 to 13, carbon atoms in the **alkyl** chain, obtained by condensation of straight-chain olefins with benzene and sulfonation of the **alkyl**benzene thus formed. "Alkanesulfonate " is a sulfonate obtained from paraffins having 12 to 16 carbon atoms by way of sulfoxidation.
"KA-sulfate" and "TA-sulfate" are the salts of sulfated, substantially sat ate" is a product containing about 10% of active oxygen of the approximate composition NaBO.sub.2.H.sub.2 O.sub.2.3H.sub.2 O. "EDTA" and "HEDP" are the salts of nitrilotriacetic acid, ethylenediaminetetraacetic acid and hydroxyethanediphosphonic acid, respectively. "CMC" is the salt of carboxymethylcellulose.
"Stilbene brightener" is a compound of Formula I on page 12, in which R.sub.1 represents an anilino **residue** and R.sub.2 represents a morpholino **residue** "Pyrazoline brightener" is a compound of Formula III on page 13, in which R.sub.7 represents a sulfamoyl **residue** and R.sub.8 represents chlorine. In all the examples the amounts given relate to the pure substances. These substances may contain accompanying substances, depending on the preparation as, for example, water, sodium sulfate, sodium chloride, sodium **carbonate**, etc. Since such accompanying substances do not in any way impair the activity of the individual substances

------ 6479374 classes:1 438/601 1 438/624 1 438/637 1 438/594 1 438/476 1 438/786 score: 618

keywords: amount of water; water; silicon oxide; substrate; removing; polyethylene glycol; polyethylene; carbona te; propylene glycol; propylene; ethylene glycol; acetic; hydroxide; etching; aqueous solution; alkyl; organic; sub strates; etch; photoresist; claimed; corresponding; tetramethylammonium; solution; hydrogen; silicon; coating; comp ounds; solvent; aqueous; metal; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; nitrogen; hydroxyl; functional groups; Stirring; derivatives; oxalic; formic; hydrochloric acid; hydrochloric; sulfuric; potassium; dimethyl; evap oration; novel; satisfactory; silicon dioxide; dioxide; aluminum oxide; contamination; fluorine; vapor; nitric; die lectric constant; polymers; alkaline; chemically; dissolving; substance; protective; completion; problems; acidic; poor; tungsten; titanium nitride; nitride; titanium; aluminum; oxygen;

onnect delay is greatly suppressed, as compared to the case of the conventional circuit structures.
 The circuit structure obtained by the method of the present invention can be very advantageously used for producing a multi-layer circuit board and a semi-conductor device.
 BEST MODE FOR CARRYING OUT THE INVENTION
 Hereinbelow, the present invention will be described in more detail with reference to the following Examples and Comparative Examples, but they should not be construed as limiting the scope of the present invention.
 EXAMPLE 1
 0.74 g of methyltriethoxysilane, 2.4 g of tetraethoxysilane, 0.68 g of

polyethylene glycol monomethacrylate having a number average molecular weight of 360 and 0.34 g of **polyethylene** glycol dimethacrylate having a number average molecular weight of 540 were dissolved in a mixed solvent of 2.0 g of **N-methyl**pyrrolidone and 1.0 g of **propylene glycol** methyl ether acetate. To the resultant solution were added 0. ator layer to obtain a laminate structure as shown in FIG. 1 which has a **photoresist** layer having a thickness of 1.05 .mu.m. A test pattern image was transferred to the **photoresist** layer by means of a light exposure apparatus (trade name: i-line stepper FPA300i4, manufactured and sold by CANON INC., Japan). The resultant **photoresist** layer was developed using a 2.38% **aqueous solution** of tetramethylammonium **hydroxide** to remove portions of the **photoresist** layer which had been exposed, thereby obtaining a structure as shown in FIG. 2 which has, on the surface of the preliminary insulator layer, a **photoresist** image corresponding to the test pattern image. The configuration of the test pattern will be explained below. The preliminary insulator layer (comprising the **silicon oxide**-organic polymer composite thin film) having the obtained **photoresist** image was subjected to **etching** through the **photoresist** image as a mask (i.e., a

6110451

classes:1 424/7016 1 424/7011 1 424/7015 1 424/7017 1 424/7019

score: 617

keywords: water;pyrrolidone;substrate;removing;polyethylene glycol;polyethylene;pyrrolidone;propylene glycol;propylene;ethylene glycol;acetic;triethanolamine;diethanolamine;monoethanolamine;ethanol;alkyl;organic;substrates;cleaning;claimed;ratio;solution;silicon;compounds;solvent;amine;ammonium;aqueous;metal;oxide;actid;methyl;acetate;ethyl;ethylene;glycol;ranges;carboxylic;nitrogen;substituted;chosen;ingredients;bene fits;ambient;derivatives;succinic;phosphoric;sulfuric;silicone;amphoteric;nonionic;cationic;surfactant;vinylalcohol;potassium;amides;N-alkyl;ratios;dimethyl;discloses;contacting;amines;environmental;satisfactory;recognized;synergistic;solubility;citric acid;citric;anionic;vapor;published;ammonium salt;quaternary ammonium;quaternary;phase;issued;polymers;formulation;formulations;hydrocarbon;aromatic;polymeric;frequently;neutralized;poor;oxygen;reacted;undesirable;

discloses many other anionic as well as other surfactant types and is incorporated herein by reference in its entirety. Preferred anionic detersive surfactants for use in the present compositions include ammonium lauryl sulfate, ammonium laureth sulfate, trlethylamine lauryl sulfate, triethylamine laureth sulfate, **triethanolamine** lauryl sulfate, **triethanolamine** laureth sulfate, **monoethanolamine** lauryl sulfate, **monoethanolamine** laureth sulfate, **diethanolamine** lauryl sulfate, **diethanolamine** laureth sulfate, lauric monoglyceride sodium sulfate, sodium lauryl sulfate, sodium laureth sulfate, potassium lauryl sulfate, potassium laureth sulfate, sodium lauryl sarcosinate, sodium lauroyl sarcosinate, lauryl sarcosine, cocoyl sarcosine, ammonium cocoyl sulfate, ammonium lauroyl sulfate, sodium cocoyl sulfate, sodium lauroyl sulfate, potassium cocoyl sulfate, potassium lauryl sulfate, trlethanolamine 1 lauryl sulfate, triethanol kyltaurines such as the one prepared by reacting dodecylamine with sodium isethionate according to the teaching of U.S. Pat. No. 2,658,072, N-higher **alkyl** aspartic acids such as those produced according to the teaching of U.S. Pat. No. 2,438,091, and the products sold under the trade name "MIRANOL".TM. as described in U.S. Pat. No. 2,528,378. Optional Detersive Surfactants In addition to the anionic detersive surfactant component, the compositions of the present invention can optionally contain other detersive surfactants. These include nonionic surfactants, and zwitterionic surfactants. Optional detersive surfactants, when used, are typically present at levels of from about 0.5% to about 20%, more typically from about 1% to about 10%, although higher or lower levels can be used. The total amount of detersive surfactant in compositions containing optional detersive surfactants in addition to the anionic surfactant will generally

uded in the compositions hereof.

Nonionic detersive surfactants which can be used include those broadly defined as compounds produced by the condensation of **alkyl**ene oxide groups (hydrophilic in nature) with an **organic** hydrophobic compound, which may be aliphatic or **alkyl** aromatic in nature. Examples of preferred classes of nonionic detersive surfactants are: The long chain alkanolamides; the **polyethylene** oxide condensates of **alkyl** phenols; the condensation product

of aliphatic alcohols having from about 8 to about 18 carbon atoms, in either straight chain or branched chain configuration, with ethylene oxide; the long chain tertiary amine oxides; the long chain tertiary phosphine oxides; the long chain dialkyl sulfoxides containing one short chain **alkyl** or hydroxy **alkyl** radical of from about 1 to about 3 carbon atoms; and the **alkyl** polysaccharide (APS) surfactants such as the **alkyl** polyglycosides; the **polyethylene** glycol (PEG)

6495573 classes:1 514/342 1 514/340 1 514/365 1 514/370 score: 585

keywords: water; substrate; polyethylene; propylene; triethanolamine; diethanolamine; monoethanolamine; alkyl; or ganic; claimed; corresponding; independently; ratio; solution; hydrogen; silicon; compounds; solvent; aqueous; oxide ;acid;methyl;acetate;ethyl;ethylene;glycol;concentrations;carboxylic;hydroxyl groups;nitrogen;carbonyl;hy droxyl; substituted; wetting; derivatives; magnesium; succinic; hydrochloric; phosphoric; silicone; classified; ami des; N-alkyl; dimethyl; qlycols; discloses; ammonia; contacting; resistant; substances; satisfactory; silicon dioxi de; dioxide; adding; water-soluble; fluorine; published; ethers; ketones; phase; hydrophilic; Films; polymers; formul ation; temperatures; formulations; hydrocarbon; aromatic; dissolving; substance; polymeric; oxygen; interaction; un desirable;

-1,2- and -1,3-glycol, butylene-1,4- and -2,3-glycol, pentane-1,5-diol, hexane-1,6-diol, octane-1,8-diol, neopentyl glycol, 1,4-bis-hydroxymethylcyclohexane, 2-methyl-1,3-propanediol, glycerol, trimethylolpropane, hexane-1,2,6-triol, trimethylolethane, pentaerythritol, quinitol, mannitol and sorbitol, diethylene glycol, triethylene glycol, tetraethylene glycol, **polyethylene** glycols having a molecular weight of up to 400, dipropylene glycol, polypropylene glycols having a molecular weight of up to 400, dibutyllene glycol, polybutylene glycols having a molecular weight of up to 400, 4,4'-dihydroxy-diphenylpropane, di-hydroxymethylhydroquinone, **ethanol**amine, **diethanolamine**, **triethanolamine**, 3-aminopropanol, ethylenediamine, 1,3-diaminopropane, 1-mercapto-3-aminopropane, 4-hydroxyor -amino-phthalic acid, succinic acid, adipic acid, hydrazine, N, N'-dimethylhydrazine, 4,4'-diaminodiphenylmethane, toluylenediamine, methyl

6500599

classes:1 430/2731 1 430/302

score: 569

keywords: water;pyrrolidone;acetic acid;methyl lactate;removing;polyethylene glycol;polyethylene;pyrrolid one; carbonate; propylene glycol; propylene; methyl lactate; lactate; acetic acid; acetic; hydroxide; aqueous solu tion; ethanol; alkyl; organic; substrates; residue; claimed; corresponding; solution; hydrogen; phosphonium; silicon ;coating;compounds;solvent;amine;aqueous;metal;oxide;acid;methyl;acetate;ethyl;ethylene;glycol;carboxylic ;ketone;hydroxyl groups;nitrogen;hydroxyl;functional groups;substituted;dissolution;derivatives;magnesium ;tartaric;oxalic;malic;formic;hydrochloric;phosphoric;sulfuric;cationic;surfactant;desirably;discloses;am monia; amines; novel; environmental; satisfactory; dioxide; water-soluble; fluorine; published; ketones; phase; hydr ophilic; nitric acid; nitric; Films; polymers; waste; isopropanol; hydrocarbon; aromatic; alkaline; dissolving; prot ective; problems; acidic; poor; tungsten; titanium; aluminum; oxygen;

dispersing agents are used as additives. For improving the adhesion, well-known adhesion improvers (for example, silane coupling agents and titanate coupling agents) may be used. In addition, various additives such as surfactants for improving coating properties are used as needed. The compositions for the light-heat conversion layers used in the invention are dissolved or dispersed in appropriate solvents, and applied onto **substrates** and dried. Examples of the solvents include 2-methoxyethanol, 2-methoxyethyl acetate, **propylene glycol** methylethyl acetate, methyl **lactate**, **ethyl **lactate**, **propylene glycol** monomethyl ether, **ethanol**, isopropanol, methyl ethyl ketone, N,N-dimethylformamide, N, N-dimethylacetamide, tetrahydrofuran and dioxane. They may be used either alone or as a mixed solvent thereof. The weight thereof coated is preferably from 0.5 g/m.sup.2 to 3 g/m.sup.2 by weight after drying. Less than 0.5 g/m.sup.2 gives unfavorable es or aluminates. As the cross-linking reaction used in the formation of the **organic** hydrophilic matrixes of the hydrophilic layers of the invention, the formation of covalent bonds by heat or light or the formation of ionic Page 23

bonds with multivalent metal salts is available.

As the **organic** hydrophilic polymers used in the invention, polymers having functional groups usable in the cross-linking reaction are preferred.

Preferred examples of the functional groups include --OH, --SH, --NH.sub.2,

--NH--, --CO--NH.sub.2, --CO--NH--, --O--CO--NH--, --NH--CO--NH--, --CO--OH, --CO--OH, --CO--OH, --CO--SH, --CS--SH, --SO.sub.3 H, --SO.sub.2 (O.sup.-), --PO.sub.3 H.sub.2, --PO(O.sup.31) sub.2, --SO.sub.2 --NH.sub.2, --SO.sub.2 --NH-- and the following functional groups.
##STR2##

In particular, hydroxyl, amino, carboxyl and epoxy groups are preferred. As such **organic** hydrophilic polymers of the invention, well-known

e polymers can be used, and examples thereof include polyvinyl alcohol (polyvinyl acetate having a degree of saponification of 60% or more), modified polyvinyl alcohol such as carboxy-modified polyvinyl alcohol, starch and derivatives thereof, cellulose derivatives such as carboxymethyl cellulose, salts thereof and hydroxyethyl cellulose, casein, gelatin, gum arabic, polyvinyl-pyrrolidone, vinyl acetate-crotonic acid copolymers and salts thereof, styrene-maleic acid copolymers and salts thereof, polyacrylic acid and salts thereof, polymethacrylic acid and salts thereof, **polyethylene** glycol, **polyethylene**imine, polyvinylsulfonic acid and salts thereof, polyhydroxyethyl methacrylate, polyhydroxyethyl acrylate and polyacrylamide.

These polymers may be used either alone or as a combination of two or more of them. The amount thereof used is from 20% to 99% by weight, preferably

from 25% to 95% by weight, and more preferably from 30% hydroxyl groups or alkoxyl groups at the same time to form resinous structures containing mixtures thereof. The polymers are in the sol state at a stage that there are many alkoxyl groups or hydroxyl groups, but the network resinous structures become strong with the progress of ether bonding. Further, they also have together the action that the hydroxyl groups are partly bonded to fine solid particles, thereby modifying the surfaces of the fine solid particles to change the hydrophilicity. Examples of the multivalent binding elements of compounds having the hydroxyl groups or alkoxyl groups performing the sol-gel conversion are aluminum, silicon, titanium and zirconium, which can be used in the invention. Sol-gel conversion systems due to siloxane bonds which can be most preferably used are described below. Sol-gel conversion using aluminum, titanium and zirconium can be conducted by replacing each element for silicon de

6506937

classes:1 564/86 1 564/23 1 564/39 1 564/40 1 564/41 1 564/87 1 564/88 1 564/166 1 564/170 1 564/176 1 564/177 1 564/185 1 564/186

score: 568

keywords: sulfoxide; dmso; removing; polyethylene; carbonate; ethylene glycol; acetic; hydroxide; ethanol; alkyl; o rganic; residue; claimed; sulfoxide; corresponding; solution; hydrogen; silicon; compounds; solvent; amine; aqueous; metal; acid; methyl; ethylene; glycol; concentrations; substituted; wetting; derivatives; hydroxides; magnesi um; tartaric; succinic; malonic; malic; benzoic; propionic; hydrochloric acid; hydrochloric; phosphoric; sulfuric; potassium; amides; stated; dimethyl sulfoxide; dimethyl; ammonia; extent; amines; metal ions; novel; substances; reco gnized; dioxide; adding; citric; fluorine; nitric; bath; temperatures; formulations; hydrocarbon; aromatic; alkaline; chemically; substance; protective; oxygen; reacted; undesirable;

d in experimental physiology by 2-deoxyglucose by blockade of glucose meta-bolism. The action potential-shortening effect of these substances was prevented or reduced by the simultaneous dose of the test substances. The test substances were added to the bath solution as stock solutions in propanediol. The values stated relate to measurements 30 minutes after the addition. The APD.sub.95 in the presence of DEO or HOE 234 and in the absence of the test substance serves an a control.

(c) Results:

The following values were measured:

Ex cell line, for some of the compounds according to the invention. The action strength of a compound in this model predicts the extent of the hypoglycemic potential of this compound. (h) Method Cell culture of RINm5F cells RINm5F cells were cultured at 37.degree. C. in RPMI 1640 culture medium (flow), to which 11 mol of glucose, 10% (volume/volume) of fetal calf serum, 2 mmol of glutamine and 50 .mu.g/ml of gentamycin were added. For the studies, the cells were isolated by incubation (about 3 minutes) in a Ca.sup.2+ -free medium containing 0.25% of trypsin and stored on ice. Measurement method Isolated RINm5F cells were introduced into a Plexi-glas chamber on an inverse microscope fitted with a differential interference contrast lens. A fire-polished micropipette with an opening diameter of about 1 .mu.m was placed on the cell with the aid of a micromanipulator under optical control (400-fold magnification). By applying a slight reduced p he opener for ATP-sensitive K.sup.+ channels diazoxide (100 .mu.mol) was added to the bath solution in all the experiments. All the experiments were carried out at 34.+-.1.degree. C. (c) Results (The concentrations of the compounds according to the invention in the experiments are 10.sup.-5 mol per liter) .DELTA.U (mv).sup.a) Measurement 13 (-76) n = 6 Example 1 Example 4 19 (-76) n = 3 11 (-79) n = 3Example 10 .sup.a) The measurement values from n experiments are followed by the corresponding blank values in parentheses. The blank values are the cell potentials under a dose of diazoxide. EXAMPLE 19 2-Methoxy-5-chloro-N-{5[-1-sulfonylamino-N-{methylaminothiocarbonyl}-2-chlo rophenyl]-ethyl}-benzamide ##STR34## This compound was obtained in accordance with example 10 starting from 2-Methoxy-5-chloro-N-{5-[-1-sulfonylamino-2-ch 6489080 classes:1 430/2811 1 430/2701 1 430/2881 1 430/914 score: 561

keywords: water; sulfoxide; ethanolamine; ethyl lactate; substrate; polyethylene; carbonate; propylene glycol; propylene; ethyl lactate; ethylene glycol; ethyl acetate; lactate; acetic; hydroxide; aqueous solution; alkyl; organ ic; claimed; sulfoxide; corresponding; tetramethylammonium; ratio; solution; hydrogen; phosphonium; silicon; coatin g; compounds; solvent; ammonium; aqueous; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; ranges; carboxylic; hydroxyl; groups; nitrogen; carbonyl; hydroxyl; substituted; dissolution; immersed; Stirring; derivatives; oxalic; for mic; hydrochloric acid; hydrochloric; sulfuric; silicone; cationic; potassium; dimethyl; amines; substances; solubi lity; fluorine; European; published; ethers; phase; polymers; rinsed; aromatic; phenolic; alkaline; chemically; dissolving; protective; problems; acidic; neutralized; aluminum; tetramethylammonium hydroxide; oxygen;

```
aminoaryl groups, arylamino
     groups, **alkyl** groups, alkoxy groups, acyl groups, acyloxy groups, aryl
     groups, aryloxy groups, nitro, hydroxy, and cyano. Specific examples of the most preferred **organic** basic compounds include guanidine,
     1,1-dimethylguanidine, 1,1,3,3-tetramethylguanidine, 2-aminopyridine,
     3-aminopyridine, 4-aminopyridine, 2-dimethylaminopyridine,
     4-dimethylaminopyridine, 2-diethylaminopyridine, 2-(aminomethyl)pyridine:
     2-amino-3-methylpyridine, 2-amino-4-methylpyridine, 2-amino-5-methylpyridine, 2-amino-6-methylpyridine, 3-aminoethylpyridine,
     4-aminoethylpyridine, 3-aminopyrrolidine, piperazine,
     N-(2-aminoethyl)piperazine, N-(2-aminoethyl)piperidine,
     4-amino-2,2,6,6-tetramethylpiperidine, 4-piperidinopiperidine,
     2-iminopiperidine, 1-(2-aminoethyl)pyrrolidine, pyrazole,
     3-amino-5-methylpyrazole, 5-amino-3-methyl-1-p-tolylpyrazole, pyrazine,
     2-(aminomethyl)-5-methylpyrazine, pyrimidine, 2,4-diaminopyrimid
     ereof exceeding
     10 parts by weight tend to result in reduced sensitivity and impaired
     development resistance of unexposed areas.
The above-described components of the composition of the present invention
     are dissolved in a solvent and coated on a **substrate**. Examples of solvents
     preferably used in the present invention include ethylene dichloride,
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cyclohexanone, cyclopentanone, 2-heptanone, .gamma.-butyrolactone, methyl ethyl ketone, **ethylene glycol** monomethyl ether, **ethylene glycol** monomethyl ether, 2-methoxyethyl acetate, **ethylene glycol** monomethyl ether acetate, **propylene glycol** monomethyl ether, **propylene glycol** monomethyl ether acetate, toluene, **ethyl acetate**, **methyl **lactate**, **ethyl **lactate**, methylmethoxy propionate, ethylethoxy propionate, methyl pyruvate, ethyl pyruvate, propyl pyruvate, N,N-dimethylformamide, dimethyl sulfoxide, **N-methyl**pyrrolidone, and tetrahydrofuran. These solvents can be used alone or in combinati

6475700

classes:1 430/2781 1 430/2841

score: 561

keywords: amount of water; water; hydrofluoric; silicon oxide; removing; polyethylene glycol; polyethylene; prop ylene glycol; propylene; ethylene glycol; acetic; hydroxide; etching; aqueous solution; alkyl; organic; residue; cl aimed; corresponding; tetramethylammonium; ratio; solution; hydrogen; silicon; coating; compounds; solvent; amine; a mmonium; aqueous; metal; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; diacetate; ranges; carboxylic; ketone; hydroxyl groups; nitrogen; carbonyl; hydroxyl; functional groups; substituted; chosen; balance; immersed; Stirring; magnesium; tartaric; oxalic; malic; propionic; hydrochloric acid; hydrochloric; phosphoric; sulfuric; silicone; no nionic; cationic; vinyl alcohol; improves; zinc; potassium; amides; listed; dimethyl; desirably; ammonia; resistant; metal ions; inhibit; substances; adding; water-soluble; European; published; quaternary ammonium; quaternary; keto nes; phase; hydrophilic; nitric acid; nitric; polymers; formulation; bath; waste; temperatures; aromatic hydrocarbon; hydrocarbon; aromatic; alkaline; chemically; protective; completion; acidic; titaniu m; aluminum; oxygen; species;

hylamine, triethylamine, monoisopropylamine, diisopropylamine, triisopropylamine:, n-butylamine, **monoethanolamine**, **diethanolamine**, triethnanolamine, monoisopropanolamine, diisopropanolamine, ethyleneimine, ethylenediamine, and pyridine. These alkalis can be used either individually or as a combination of two or more thereof.

Among **aqueous solution**s of the above alkalis, an **aqueous solution** of an alkali metal silicate having a pH of 12 or higher particularly allows the effects of the invention be manifested. The developing properties of an alkali metal silicate **aqueous solution** are controllable by the ratio of the **silicon oxide** (SiO.sub.2) of the silicate to the alkali metal oxide (M.sub.2 O, generally represented in terms of SiO.sub.2 /M.sub.2 O molar ratio, and the concentration. From this point of view, it is preferable to use a sodium silicate **aqueous solution** having an SiO.sub.2 /Na.sub.2 O molar ratio of 1.0 to 1.5 a

4824763

classes:1 430/258 1 430/326 1 430/329 1 430/330 1 430/331 1 510/176 1 510/407 1 510/499 score: 557

keywords: deionized water; water; pyrrolidone; substrate; removing; N-methyl pyrrolidone; pyrrolidone; N-methyl; organic; substrates; photoresist; stripping; claimed; corresponding; independently; solution; silicon; compounds; s olvent; amine; aqueous; metal; acid; glycol; carboxylic; substituted; photoresist stripper; immersed; derivatives; s ulfuric; deionized; stated; dimethyl; contacting; elevated; photoresist stripping; novel; substances; integrated circuit; dioxide; solubility; contamination; bath; coatings; temperatures; aromatic hydrocarb on; hydrocarbon; aromatic; phenolic; alkaline; dissolving; polymeric; protective; acidic; nitride; aluminum; oxygen plasma; oxygen; species;

ist easier to remove.

These and related objects may be achieved through use of the novel

stripping solution and process for **stripping** positive **photoresist** and
other difficult to remove polymeric coatings from **substrates** herein
disclosed. A positive **photoresist** in accordance with this invention has a
triamine as its principal active ingredient.

The **stripping** composition should contain from about 25 weight percent to about 100 weight percent of the triamine and from about 0 weight percent to about 75 weight percent of a suitable polar or nonpolar **organic** solvent.

The process for **stripping** positive **photoresist** from a **substrate** in accordance with this invention comprises contacting the positive **photoresist** with the above triamine composition at a temperature and time sufficient to remove the **photoresist**, typically at a temperature of about 80.degree. C. to about 120.degree. C. for a time of from about one minute to about 20 minute

Triamines which are useful in the composition and process of this invention have the general formula ##STRI## wherein R.sub.1 and R.sub.2 are, independently in each case, a difunctional straight or branched chain hydrocarbyl or substituted hydrocarbyl group having from about 2 to about 20 carbon atoms, including straight and branched chain, heterocyclic, aromatic, halogen, hydroxy and cyano substituted aliphatic groups. Suitable specific examples of operable triamines for the composition and process of this invention include diethylene triamine, 1 benzyl- and 1 cyanoethyl- substituted diethylene triamine, N-(2 hydroxyethyl) diethylene triamine, lauryl diethylene triamine, N-(2 hydroxyethyl) diethylene triamine, N-(2 hydroxyethyl) diethylene triamine is diethylene triamine. Suitable specific examples of polar **organic** solvents for the composition and process include **N-methyl pyrrolidone**, di

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classes:1 430/2701 1 326/905 1 326/910

score: 534

keywords: water;ethanolamine;substrate;polyethylene glycol;polyethylene;propylene glycol;propylene;ethyle ne glycol;lactate;hydroxide;etching;diethanolamine;ethanol;alkyl;organic;substrates;claimed;corresponding;sulfone;independently;tetramethylammonium;solution;hydrogen;phosphonium;silicon;coating;compounds;solven t;ammonium;aqueous;metal;acid;methyl;ethylene;glycol;ketone;nitrogen;carbonyl;hydroxyl;functional groups;substituted;ingredients;amphoteric;nonionic;cationic;stated;dimethyl;ammonia;amines;water-soluble organic;water-soluble;anionic;ketones;hydrophilic;Films;polymers;formulation;compositions used;hydrocarbon;aromatic;phenolic;alkaline;chemically;dissolving;acidic;tetramethylammonium hydroxide;alkanolamines;

- based on 100 parts by weight of the total resin components in the radiation-sensitive resin composition.

A dye and/or a pigment may also be mixed so that latent images at exposed areas can be rendered visible and any influence of halation can be lessened at the time of exposure, and an adhesion aid may be mixed so as to improve adhesion to **substrates**.

As other additives, they may further be halation preventive agents, storage stabilizers, anti-foaming agents and shape improvers, which may specifically include 4-hydroxy-4'-methylcalcon.

Solvents

The positive radiation-sensitive resin composition of the present invention is, when used, dissolved in a solvent so as to be in a solid concentration of, e.g., from 2 to 50% by weight, followed by filtration with a filter having a pore size of, e.g., about 0.2 .mu.m, and prepared into composition solutions.

The solvent may include, e.g., ethers, esters, ether esters, ketone esters, ketones

glycol

di-n-propyl ether, diethylene glycol di-n-butyl ether, **ethylene glycol**
monomethyl ether acetate, **ethylene glycol** monoethyl ether acetate,
propylene glycol monomethyl ether acetate, **propylene glycol** monoethyl
ether acetate, **propylene glycol** mono-n-propyl ether acetate, ethyl
acetate, n-propyl acetate, n-butyl acetate, isopropenyl acetate,
3-methoxybutyl acetate, 3-methyl-3-methoxybutyl acetate, ethyl
hydroxyacetate, ethyl ethoxyacetate, methyl acetoacetate, ethyl
acetoacetate, isopropenyl propionate, 3-methyl-3-methoxybutyl propionate,
ethyl **lactate, ethyl 2-hydroxy-2-methylpropionate, methyl
3-methoxypropionate, ethyl 3-methoxypropionate, methyl 3-ethoxypropionate,
ethyl 3-ethoxypropionate, 3-methyl-3-methoxybutyl butyrate, methyl
2-hydroxy-3-methylbutyrate, methyl ethyl ketone, cyclohexanone, 2-heptane,
3-heptane, 4-heptane, N,N-dimethylformamide, N,N-dimethylacetamide,
N-methylpyrrolidone, toluene, and xyle
aline aqueous

aline aqueous solutions prepared by dissolving at least one of alkaline compounds such as alkali metal **hydroxide**s, ammonia water, **alkyl**amines, alkanolamines, heterocyclic amines, tetraalkylammonium **hydroxide**s, choline, 1,8-diazabicyclo[5.4.0]-7-undecene and 1,5-diazabicyclo[4.3.0]-5-nonene so as to be in a concentration of usually from 1 to 10% by weight, and preferably from 2 to 5% by weight. Particularly preferred alkaline developing solutions are **aqueous solution**s of tetraalkylammonium **hydroxide**s.

To developing solutions formed of such alkaline **aqueous solution**s, water-soluble **organic** solvents or surface-active agents as exemplified by

methanol and **ethanol** may also be added in appropriate quantity. Incidentally, when such developing solutions formed of alkaline aqueous solutions are used, it is common to carry out water washing after the development. In the production of devices, the lower-layer **organic** films

4549968

classes:1 210/750 1 252/178 1 252/18828 1 252/392 1 252/393 1 422/13 1 422/16 1 422/17

keywords: water; hydroxide; aqueous solution; residue; ratio; solution; amine; aqueous; acid; severe; ambient; state d; amines; dioxide; adding; toxic; formulations; alkaline; substance; problems; oxygen;

inbelow for about five months. The procedure consisted of taking the stored samples and first vigorously shaking the sample bottles to ensure homogeneity and to loosen any **residue** which may have adhered to the sample bottle walls. A 20 mL aliquot of each sample was then drawn into a 30 mL syringe, which was subsequently fitted with a 25 mm membrane filter holder containing a 0.22 micron pore size membrane.The membranes were previously dried for about 2 hours at 100.degree. C., cooled in a desiccator, and then weighed. The 20.0 mL aliquots were filtered through the membranes, yielding dark but clear filtrates. The clarity of the filtrates indicated that the 0.22 micron membranes were of sufficient pore size to quantitatively retain the sludge particles. The brown **residue**s obtained on the membrane filters were dried overnight in a desiccator over prepared silica gel (the **residue**s were not heated lest possibly losing the mo

6506318 classes:1 252/70 1 106/13

score: 518

keywords: water;pyrrolidone;ethyl lactate;pyrrolidone;carbonate;propylene glycol;propylene;ethyl lactate; ethylene glycol; lactate; formate; ethanol; alkyl; organic; substrates; residue; claimed; ratio; solution; compounds ;ammonium;aqueous;metal;acid;methyl;acetate;ethyl;ethylene;glycol;concentrations;carboxylic;nitrogen;hydr oxyl; magnesium; succinic; malonic; potassium; nitrate; effectiveness; glycols; discloses; liquid phase; novel; envi ronmental; dioxide; adding; teaches; solubility; contamination; spraying; carboxylate; phase; issued; formulation; b ath; waste; toxic; temperatures; formulations; alkaline; chemically; problems; oxygen; species;

/30% by weight **ethylene glycol** solution has a melting point of -18.degree. C.

EXAMPLE 42

The addition of 50% by weight of a 50% mixture of **ethyl **lactate** in water to a concentrated, filtered corn steep liquor (containing 50% water and 50% solids comprising mostly lactic acid and sugars) caused a reduction in freezing point from -11.degree. C. to -16.degree. C. The addition of 2% by weight sodium **lactate** further reduced the freezing point to -20.degree. C.

A mixture of 60% by weight water, 20% by weight sodium **lactate**, 2% by weight proline (an amino acid), 8% by weight sorbitol and 10% by weight sodium **pyrrolidone** carboxylate (sodium PCA) was prepared. No crystal formation at -35. degree. C. was observed. The pH was 6.57. For comparison a 50% by weight solution **propylene glycol** has a freezing point of -36.degree. C.

EXAMPLE 44

A mixture of 12% by weight **methyl **lactate**, 44% by weight methyl glucoside and 44% by weight water

was prepared. A melting point of -18.degree. C.

was observed. The mixture had a pH of 5.

EXAMPLE 45

A mixture containing 35% by weight **methyl **lactate**, 35% by weight methyl glucoside and 30% by weight water has a melting point of -21.degree. C. as determined by DSC.

EXAMPLE 46

A filtered concentrated liquid **residue** of a 50% mixture of corn stillage and steepwater containing 50% by weight water with a freezing point of -12.degree. C. is heated to 90.degree. C. and treated with 5% **ethanol** for 8 hours. The resulting mixture has a freezing point of -17.degree. C. The addition of 2% sodium **lactate** further reduces the freezing point to -21.degree. C.

EXAMPLES 47-53
Additional deicing and anti-icing fluids containing potassium **carbonate**

were prepared in accordance with the present invention. The results are set forth below in Table 3.

TABLE 3

Example 47 48 49 50 51 52 53

Composition
Methyl Glucosid

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classes:1 430/2701 1 430/905 1 430/910

score: 515

keywords: water;ethyl lactate; substrate; propylene glycol; propylene; ethyl lactate; ethylene glycol; ethyl ac etate; lactate; hydroxide; etching; aqueous solution; alkyl; organic; substrates; photoresist; stripping; claimed; c orresponding; independently; tetramethylammonium; ratio; solution; hydrogen; tetrabutyl; silicon; coating; compoun ds; solvent; amine; ammonium; aqueous; acid; methyl; acetate; ethyl; ethylene; glycol; concentrations; ester groups; n itrogen; hydroxyl; substituted; dissolution; balance; Stirring; cationic; surfactant; listed; stated; amines; novel; recognized; integrated circuit; silicon dioxide; dioxide; solubility; European; quaternary ammonium; quaternary; phase; ammonium hydroxide; Films; polymers; formulation; bath; isopropanol; temperatures; formulations; hydrocarbo n; aromatic; phenolic; alkaline; chemically; dissolving; poor; aluminum; involving; tetramethylammonium hydroxide; oxygen; reacted; interaction;

osition of the invention can be prepared by dissolving the components of the **photoresist** in a suitable solvent such as, for example, **ethyl **lactate**, **ethylene glycol** monomethyl ether, **ethylene glycol** monomethyl ether acetate, **propylene glycol** monomethyl ether acetate and 3-ethoxyethyl propionate. Typically, the solids content of the composition varies between about 5 and 35 percent by weight of the total weight of the **photoresist** composition. The resin binder and photoactive components should be present in amounts sufficient to provide a film coating layer and formation of good quality latent and relief images. See the examples which follow for exemplary preferred amounts of resist components. The compositions of the invention are used in accordance with generally known procedures. The liquid coating compositions of the invention are applied to a **substrate** such as by spinning, dipping, roller c otoresist coating over the **substrate**, the developed **substrate** may be selectively processed on those areas bared of resist, for example by chemically **etching** or plating **substrate** areas bared of resist in accordance with procedures known in the art. For the manufacture of microelectronic **substrates**, e.g., the manufacture of silicon dioxide wafers, suitable etchants include a gas etchant, e.g. a halogen plasma etchant such as a chlorine or fluorine-based etchant such a Cl.sub.2 or CF.sub.4 /CHF.sub.3 etchant applied as a plasma stream. After such processing, resist may be removed from the processed **substrate** using known **stripping** procedures. All documents mentioned herein are incorporated herein by reference. The following non-limiting examples are illustrative of the invention. EXAMPLES 1-6 Syntheses of Cage and Lactone Monomers EXAMPLE 1 Synthesis of Ethyl Fenchol Methacrylate ##STR11##

Amount

Materi

----- 6506759 classes:1 514/255 1 514/365 1 514/419 1 514/415 1 514/428 1 514/392 1 514/307 1 546/87 1 546/85 1 546/146 1 546/147 1 546/150 1 548/146 1 548/452 1 548/494 1 548/495 1 548/567 1 548/569 1 548/566 1 544/402 score: 509

keywords: water; sulfoxide; dmso; acetic acid; substrate; polyethylene; carbonate; ethylene glycol; ethyl acetate; lactate; acetic acid; acetic; hydroxide; aqueous solution; ethanol; alkyl; organic; residue; claimed; sulfoxide; coresponding; sulfone; independently; solution; hydrogen; compounds; solvent; amine; ammonium; aqueous; metal; acid; methyl; acetate; ethyl; ethylene; glycol; concentrations; carboxylic; ketone; nitrogen; carbonyl; hydroxyl; substitut ed; wetting; ambient; Stirring; derivatives; magnesium; succinic; oxalic; benzoic; propionic; formic; organic acids; hydrochloric; phosphoric; classified; potassium; listed; dimethyl; effectiveness; glycols; disc loses; ammonia; evaporation; amines; inhibit; novel; substances; recognized; adding; fluorinated; citric acid; citric c; carboxylate; ammonium salt; ethers; phase; issued; bath; isopropanol; formulations; hydrocarbon; aromatic; alkali

ne; aluminum; involves; oxygen; reacted;

_____ 6482567

classes:1 430/2701 1 430/920 1 430/921 1 540/460 1 540/461 1 540/477 1 548/420 1 548/425 1 548/452 1 546/

183 1 568/30 1 568/31 1 568/34

score: 473

keywords: hydrofluoric;ethyl lactate;substrate;propylene glycol;propylene;ethyl lactate;ethylene glycol;l actate; hydroxide; etching; alkyl; substrates; etch; photoresist; claimed; corresponding; independently; hydroxylam ine; solution; silicon; coating; compounds; solvent; amine; ammonium; aqueous; oxide; acid; methyl; acetate; ethyl; eth ylene; glycol; concentrations; ester groups; ketone; hydroxyl groups; carbonyl; hydroxyl; functional groups; subst ituted; dissolution; malonic; cationic; nitrate; stated; consists; amines; novel; silicon dioxide; dioxide; vapor; Eu ropean; published; Films; dimensions; polymers; formulation; temperatures; aromatic hydrocarbon; hydrocarbon; arom atic; phenolic; alkaline; chemically; dissolving; involving; oxygen plasma; oxygen; reacted; undesirable;

minum-aluminum oxide microelectronic wafer. Gallium arsenide, ceramic, quartz or copper **substrates** may also be employed. Printed circuit board **substrates** such as copper clad laminates are also particularly preferred. The **photoresist**s of the invention will be particularly useful for circuit board imaging, including through hole and other aperture plating. Typical printed circuit board **substrates** have one or more copper layers interleaved with resin layers, such as epoxy layers.

Substrates used for liquid crystal display and other flat panel display applications are also suitably employed, e.g. glass **substrates**, indium tin oxide coated **substrates** and the like.

- A liquid coating resist composition may be applied by any standard means such as spinning, dipping or roller coating. **photoresist**s of the invention also may be formulated and applied as dry film resists, particularly for printed circuit board manufacture applications. The expos
 - ed of **photoresist** in accordance with procedures known in the art. Suitable etchants include a hydrofluoric acid **etching** solution and a plasma gas etch such as an oxygen plasma etch.
- All documents mentioned herein are incorporated herein by reference. The following non-limiting examples are illustrative of the invention. EXAMPLE 1

A PAG of the invention of the structure NC(1-naphthyl)C.dbd.NOS(0).sub.2 C.sub.6 F.sub.5 can be prepared by reaction NCCH.sub.2 --(1-naphthyl) with amyl nitrate to provide the oxime NCCH(.dbd.NOH) (1-naphthyl). That oxime is reacted with pentafluorobenzenesulfonyl chloride to provide NC(1-naphthyl)C.dbd.NOS(0).sub.2 C.sub.6 F.sub.5.

EXAMPLE 2

Photoresist Preparation and Lithographic Processing

A **photoresist** of the invention is prepared by mixing the following components with amounts expressed as weight percent based on total weight of the resist compositions:

Resist components

Amount

6479211

classes:1 430/2701 1 430/905

score: 451

keywords: water; dimethylsulfoxide; propylene carbonate; ethyl lactate; acetic acid; substrate; propylene carbo nate; carbonate; propylene glycol; propylene; ethyl lactate; ethylene glycol; ethyl acetate; lactate; acetic acid ;acetic;hydroxide;etching;aqueous solution;alkyl;organic;residue;photoresist;claimed;corresponding;indepe ndently; dimethylsulfoxide; tetramethylammonium; ratio; solution; hydrogen; phosphonium; silicon; coating; compoun ds; solvent; amine; ammonium; aqueous; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; carboxylic; ketone; nitro gen; carbonyl; hydroxyl; functional groups; substituted; dissolution; Stirring; derivatives; hydrochloric acid; hy drochloric; sulfuric; nonionic; classified; surfactant; potassium; dimethyl; butyl acetate; discloses; evaporation ; elevated; amines; integrated circuits; satisfactory; integrated circuit; dioxide; solubility; aluminum oxide; fl uorine;introducing;European;published;ammonium salt;quaternary ammonium;quaternary;ethers;hydrophilic;bat h; rinsed; hydrocarbon; aromatic; alkaline; dissolving; protective; completion; problem s; neutralized; titanium; aluminum; tetramethylammonium hydroxide; oxygen; reacted;

S1/S2 (70/30)W-2 1.1 2 25 6 nm \$1/\$2/\$5 (70/27/3)W-3 25g (25) 20 5 nm 1.1 Page 30

report09903064.txt W-1(70/30)(26)S1/S2 26g 40 0.7 3 6 nm Comparative Example (80/20)S1/S2 none 1g 1 (R1) 3 15000 18 nm 0.1 S1/S2 (80/20)W-42g 1 (1)0.4 300 12 nm 1

As apparent from the results in Table 9, the samples of Comparative

Examples have problems in the number of development failures and the
generation of edge roughness. On the other hand, the positive **photoresist**
compositions for far ultraviolet exposure of the present invention are
excellent in the sensitivity, resolution, adhesion to a **substrate** and dry
etching resistance and furthe
pitch.

EXAMPLES 1h TO 26h AND COMPARATIVE EXAMPLES 1h AND 2h

1.4 g of a resin shown in Table 10, which was synthesized in Synthesis
 Examples above, 0.18 g of a photo-acid generator, 11.4 g of solvents (at a
 mixing ratio shown in Table 10), a surfactant (added in an amount of 1 wt
 % based on all solid contents in the composition) and 10 mg of an **organic**
 basic compound were mixed as shown in Table 10 and filtered through a
 0.1-.mu.m microfilter to prepare positive **photoresist** composition
 solutions of Examples 1h to 26h and Comparative Examples 1h and 2h.

In Examples and Comparative Examples, the photo-acid generator used was triphenylsulfonium triflate. Resin R1 used in Comparative Example of Table 10 was the resin used in Example 1 of JP-A-11-109632.

The solvents used were:
S1: **ethyl **lactate**
S2: **propylene glycol** monomethyl ether acetate
S3: .gamma.-butyrolactone

S4: **propylene **carbonate**

S5: ethylene **carbonate**

S6: butyl acetate S7: 2-heptanone

57: 2-11 The

----- 5646240

classes:1 528/403 1 524/604 1 524/722 1 524/729 1 524/755 1 524/765 1 524/770 1 524/777 1 524/779 1 524/8 29 1 525/472 1 525/509 1 525/510 1 525/515 1 528/230 1 528/248 1 528/253 1 528/254 1 528/258 1 528/393 1 528/421 1 528/422 1 528/423

score: 446

keywords: amount of water; deionized water; water; hydrofluoric; sulfoxide; chelating; propylene carbonate; pyrr olidone; removing; polyethylene; pyrrolidone; propylene carbonate; carbonate; propylene glycol; propylene; ethyle ne glycol; ethyl acetate; hydroxide; chelating; aqueous solution; triethanolamine; ethanol; alkyl; organic; fluori de; substrates; residue; cleaning; sulfoxide; corresponding; hydroxylamine; hydrozine; ratio; solution; hydrogen; phosphonium; coating; compounds; solvent; amine; ammonium; aqueous; metal; oxide; acid; methyl; acetate; ethyl; ene; glycol; concentrations; carboxylic; ketone; hydroxyl groups; nitrogen; hydroxyl; functional groups; substituted; chosen; dissolution; blend; benefits; Stirring; derivatives; hydroxides; magnesium; succinic; oxalic; benzoic; propionic; formic; hydrochloric; phosphoric; sulfuric; silicone; nonionic; cationic; zinc nitrate; zinc; potassium; nitrate; polyols; amides; deionized; ratios; dimethyl sulfoxide; dimethyl; desirably; butyl acetate; ammonia; evaporation; extent; elevated; consists; amines; resistant; metal ions; novel; substances; satisfa

ctory; dioxide; adding; fluorinated; synergistic; water-soluble; solubility; introducing; vapor; quaternary ammoni um; quaternary; ethers; ketones; nitric; Films; polymers; formulation; waste; temperatures; aromatic hydrocarbon; hy drocarbon; aromatic; phenolic; alkaline; chemically; dissolving; substance; polymeric; protective; completion; prob lems; acidic; neutralized; poor; tungsten; nitride; titanium; aluminum; involves; oxygen; reacted;

content of the modified amino resin, of pentane were added under vigorous stirring. Stirring was continued further for about four minutes to disperse the reaction mixture uniformly, whereby a thermosetting expansion-forming composition was obtained.

The composition was treated in a similar manner to Example 120, subjected to foaming at about 37.degree. C., which was the temperature of the composition at the time of foaming, and then cured, Whereby an elastic foam was obtained. As a result of tests, the elastic foam so obtained was found to have 12 g/l bulk density and 21 mm deflection at break.

EXAMPLE 122
In a 21 flask equipped with a stirrer, a thermometer and a condenser, 300.3
g of paraformaldehyde (80% grade, 8.0 moles in terms of 100%
formaldehyde), 170.0 g of deionized water and 100 g of **ethanol** were
charged, followed by adjustment of pH to 13.0 with a 30% **aqueous solution**
of caustic soda. To the resultant mixture, 604.7 g (

Page 31

----- 6479039 classes:1 424/61 1 424/407

score: 434

keywords: water; removing; propylene glycol; propylene; ethylene glycol; alkyl; organic; claimed; corresponding; ratio; solution; coating; compounds; solvent; amine; ammonium; aqueous; acid; methyl; acetate; ethyl; ethylene; glycol; ranges; concentrations; beneficial; hydroxyl groups; hydroxyl; substituted; ingredients; benefits; derivatives; listed; dimethyl; butyl acetate; amines; resistant; inhibit; substances; satisfactory; dioxide; contamination; vapor; published; quaternary ammonium; quaternary; ketones; polymers; formulation; coatings; formulations; phenolic; chemically; polymeric; neutralized; titanium; aluminum; species; interaction;

e emollients and mitigators include allantoin, its metallic salts, and **organic** conjomers. Emollients and mitigators can be employed in amounts ranging between about 0.001-5.0 percent by weight, preferably between about 0.01-3.0 percent by weight, and more preferably between about 0.05-2.0 percent by weight.
One or more solvents can be used to facilitate suspension of solid

One or more solvents can be used to facilitate suspension of solid components in the composition of the present invention. The solvents are preferably non-aqueous. Such solvents are well known to those skilled in the art, and exemplary types of solvents compatible with the composition of the present invention include alkanes, alkanols, ketones, esters including acetates, amides, ethers, alcohols, glycol-ethers and nitroparaffins. Specific examples of these types of solvents include ethyl ether, petroleum ether, **methyl acetate**, acetone, cyclohexane, ethyl acetate, methyl ethyl ketone, carbon tetrachloride, ethyl alcohol, n-b

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classes:1 521/50 1 428/365 1 428/3692 1 428/524 1 524/442 1 525/472 1 525/473 1 525/509 1 528/230 1 528/2 48 1 528/253 1 528/254

score: 432

keywords: amount of water; deionized water; water; hydrofluoric; sulfoxide; chelating; propylene carbonate; pyrr olidone; removing; polyethylene; pyrrolidone; propylene carbonate; carbonate; propylene glycol; propylene; ethyle ne glycol; ethyl acetate; hydroxide; chelating; aqueous solution; triethanolamine; ethanol; alkyl; organic; fluori de; substrates; residue; cleaning; sulfoxide; corresponding; hydroxylamine; hydrazine; ratio; solution; hydrogen; ph osphonium; coating; compounds; solvent; amine; ammonium; aqueous; metal; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; concentrations; carboxylic; ketone; hydroxyl groups; nitrogen; hydroxyl; functional groups; substituted; chosen; dissolution; blend; benefits; Stirring; derivatives; hydroxides; magnesium; succinic; oxalic; benzoic; propi onic; formic; hydrochloric; phosphoric; sulfuric; silicone; nonionic; cationic; zinc nitrate; zinc; potassium; nitrate; polyols; amides; deionized; ratios; dimethyl sulfoxide; dimethyl; desirably; butyl acetate; ammonia; evaporatio n; extent; elevated; consists; amines; resistant; metal ions; novel; substances; satisfa ctory; dioxide; adding; fluorinated; synergistic; water-soluble; solubility; introducing; vapor; quaternary ammoni um; quaternary; ethers; ketones; nitric; Films; polymers; formulation; waste; temperatures; aromatic hydrocarbon; hydrocarbon; aromatic; phenolic; alkaline; chemically; dissolving; substance; polymeric; protective; completion; prob lems; acidic; neutralized; poor; tungsten; nitride; titanium; aluminum; involves; oxygen; reacted;

- ith a 20% **aqueous solution** of caustic soda. To the resultant mixture, 604.7 g (2.0 moles) of the diguanamine >formula (2)! prepared in the same manner as in Example 3 were added and mixed. The resulting mixture was reacted at 70.degree. C. for 1 hour while its pH was maintained at 10.0-10.5.

In the next place, 41.6 g (0.4 mole) of sodium bisulfite were added to the reaction mixture and while maintaining its pH at 10.0-10.5, a reaction was conducted at 80.degree. C. for 2 hours. The reaction mixture was adjusted to pH 7.0 with a 20% **aqueous solution** of sulfuric acid, whereby a modified amino resin was obtained.

Deionized water was added to the modified amino resin to adjust the solid resin content of the resulting solution to 74.0 wt. %. To the resulting mixture, 3.0 wt. % and 1.5 wt. %, each based on the solid content of the modified amino resin, of formic acid and sodium **alkyl**sulfonate ("Ratemur PS", trade name; 40% grade, produ

6491970

classes:1 427/130 1 427/131 1 427/132 1 427/289 1 427/404 1 427/4071 1 427/420 1 427/4342

score: 427

keywords: water; substrate; removing; polyethylene; propylene; alkyl; organic; substrates; cleaning; claimed; corre sponding; sub; independently; ratio; solution; hydrogen; coating; compounds; solvent; ammonium; metal; oxide; acid; me

thyl; acetate; ethyl; ethylene; glycol; ranges; concentrations; carboxylic; ketone; beneficial; hydroxyl groups; nit rogen; hydroxyl; substituted; blend; wetting; ambient; phosphoric; silicone; vinyl alcohol; improves; zinc; polyols; listed; desirably; effectiveness; evaporation; contacting; substances; satisfactory; adding; fluorinated; vapor; qu aternary ammonium; quaternary; ethers; ketones; Films; polymers; formulation; coatings; formulations; hydrocarbon; aromatic; phenolic; dissolving; polymeric; problems; acidic; titanium; involves; reacted;

rmance of the agent if E and A were to be ortho to each other. Preferably, the plurality of magnetic particles are first prepared as a concentrated magnetic particle dispersion prior to its addition to the binder. The concentrated magnetic particle dispersion can be prepared by procedures known to those in the dispersion art. The dispersion can be prepared by the use of a dispersing machine, for example, a high speed impeller mill, an attritor, or a sand mill. The concentrated magnetic particle dispersion can be diluted with a suitable non-aqueous **organic** solvent to make a magnetic coating composition. Typically, the non-aqueous **organic** solvent has dissolved or dispersed therein a binder, as described above. Solvents useful for dilution of the concentrated magnetic dispersion include ketones such as acetone, methyl ethyl ketone, methyl isobutyl ketone, cyclohexanone,

isophorone; esters such as **methyl acetate**, **ethyl acetate**, bu

6482848

classes:1 514/418 1 548/467 1 548/468 1 548/486

score: 426

keywords: water; dmso; dimethylsulfoxide; co-solvent; substrate; removing; polyethylene glycol; polyethylene; pro pylene; ethyl acetate; acetic; co-solvent; hydroxide; alkyl; organic; substrates; residue; claimed; corresponding; i ndependently; dimethylsulfoxide; ratio; solution; hydrogen; coating; compounds; solvent; amine; ammonium; aqueous; m etal; acid; methyl; acetate; ethyl; glycol; concentrations; carboxylic; beneficial; nitrogen; carbonyl; substituted; chosen; severe; ingredients; ambient; derivatives; hydroxides; magnesium; tartaric; succinic; malic; formic; organic acids; hydrochloric acid; hydrochloric; phosphoric; sulfuric; surfactant; zinc; potassium; deionized; listed; N-al kyl; stated; dimethyl; effectiveness; extent; contacting; consists; amines; inhibit; novel; substances; adding; solub ility; citric acid; citric; European; published; quaternary ammonium; quaternary; phase; nitric; polymers; formulat ion; bath; coatings; temperatures; formulations; hydrocarbon; aromatic; substance; polymeric; acidic; titanium; invo lves;involving;oxygen;species;reacted;interaction;

- tisol Based: This formulation uses Captisol and an acidic agent to form an in situ salt at a pH of 1.5-2.0 to compound and lyophilize solutions of drug at concentrations of 20.0-25.0 mg/mL. The lyophilized cake is reconstituted with an IV fluid to provide a stable infusate at 2 mg/mL or higher at pH 3.
- (b) Non-Captisol based: This formulation uses small amounts of a surfactant such as Polysorbate-80 or Cremophor EL and an acidic agent to form an in-situ salt at a pH of 1.5-2.0 to compound and lyophilize solutions of drug at concentrations of 20.0-25.0 mg/mL. The lyophilized cake is reconstituted with cosolvent-surfactant based aqueous diluent such as PEG-300-Polysorbate 80 or PEG-300-Cremophor EL to provide a stable infusate at 2 mg/mL or higher at pH 3.
- (2) Sterile API fill:
- The drug is filled as a sterile powder fill in a container and will be reconstituted with a specific **co-solvent**--surfactant based aqueous diluent
- ide a stable infusate at 2 mg/mL or higher of drug at pH 3.
- [B] Solution Concentrate to be Diluted to a Stable Infusate (Table 2) The drug is solubilized in a non-aqueous mixture of **co-solvent**s and
- surfactants at a high concentration such that it can be diluted with aqueous diluents to a stable infusate. The concentration of the drug in the infusate is at a concentration of 2 mg/mL or higher, at pH 3. The total levels of the **co-solvent** is less than 15% and the levels of surfactant is than 0.5%.

TABLE 1

Formulation

(1) Solid

formulations

Lyophilized - Captisol based Attributes Sterile API Fill based

Lyophilized Non-Captisol

Dose/50 CC 200-300 200-300

300-400 vial (mgs)

Sterile API fill NA

NΑ

300-400 mg

```
in vial
                                          200-300
    Composition - drug (mg)
                                                       dru
                                     20-30
     tion - drug (mg/mL)
                                                pН
                                           3.0
               pН
     3.0
    Prelyophilate Acid (Molar)
                                            1.4
                                                       drug (mg/mL)
     20-30
                NA
                                             0-10
                                                        Acid (Molar)
                  Antioxidant (mg/mL)
      1.4
                  Captisol (mg/mL)
                                          200-300
                                                       Antioxidant (mg/mL)
     0-10
                                                        Filler (mg/mL)
                  Water for Injection qs to 1.0 mL
     20 - 30
                                          1.5-2.0
                                                       Polysorbate-80 (mg)
     0-50
                                                       Water for Injection
     to 1.0 mL
                                                       рН
    Acids used: Methane sulfonic acid, Tartaric acid, Citric acid, succinic
     acid is used in a 1:1.4 molar ratio for in situ salt formation
    Cosolvents- PEG-300, PEG-400
    Surfactants: Polysorbate-80, Cremophor EL
    Captisol .RTM.: Sulfobutylether Cyclodextrin
    Drug: Compound of Example 2
TABLE 2
```

Composition

classes:1 514/2641 1 514/2581 1 514/2641 1 544/279

6506419 _____ classes:1 424/732 1 424/52

score: 407

keywords: water; gallic; removing; polyethylene glycol; polyethylene; carbonate; propylene glycol; propylene; ace tic; gallic acid; aqueous solution; ethanol; alkyl; organic; residue; claimed; independently; ratio; solution; galli c; hydrogen; compounds; solvent; aqueous; acid; methyl; acetate; ethyl; glycol; ketone; hydroxyl; Stirring; derivative s;nonionic;potassium;discloses;substances;adding;water-soluble;citric acid;citric;published;phase;hydroph ilic; phenolic; substance; completion; oxygen;

```
94.41
     mposition 22)
          Composition 22
                                               99.00
Based on the above results, it is readily understood that the compositions
     of the present invention provide excellent stability of proanthocyanidin
     in comparison with the compositions of control groups.
REFERENCE EXAMPLE 1
Production of a Turbid Apple Juice
One ton of washed fruits of an apple variety "Fuji" were applied to a
     crusher and an **aqueous solution** of 10 kg of 10% ascorbic acid was added
     thereto. Next, the juice was squeezed using a press and applied to a
     screen of 60 meshes. Thereafter, this was sterilized at 95.degree. C. for
     20 seconds using a flash sterilization machine, immediately cooled and
     then centrifuged to obtain the turbid apple juice.
REFERENCE EXAMPLE 2
Production of a Casked Grape Fermentation Liquid
Ten tons of fruits of a grape variety "Cabernet Sauvignon" were applied to
     a crusher, mixed with 800 g of potassium pyrosulfite and then with
              6498163
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keywords: water; sulfoxide; dmso; dimethylsulfoxide; substrate; carbonate; propylene glycol; propylene; ethylene glycol; ethyl acetate; lactate; acetic; hydroxide; aqueous solution; ethanol; alkyl; organic; residue; claimed; sulf oxide; corresponding; independently; dimethylsulfoxide; solution; hydrogen; compounds; solvent; amine; ammonium; aq ueous; metal; oxide; acid; methyl; acetate; ethyl; ethylene; glycol; monolaurate; concentrations; carboxylic; nitroge n;carbonyl;functional groups;substituted;Stirring;derivatives;magnesium;propionic;hydrochloric;potassium; listed; stated; ammonia; contacting; elevated; amines; inhibit; substances; recognized; adding; solubility; aluminum oxide; carboxylate; ethers; phase; ammonium hydroxide; formulation; bath; isopropanol; rinsed; temperatures; formu lations; hydrocarbon; aromatic; dissolving; protective; acidic; neutralized; aluminum; reacted; interaction;

ed to a suspension of insect cell lysis buffer comprised of 150 mM NaCl, 50 mM Tris pH 7.5, 1 mM DTT, 1% NP-40, 2 Page 34

mM EGTA, 1 mM sodium vanadate, 1 mM PMSF, 1 .mu.g/mL each of leupeptin, pepstatin, and aprotinin. Insect cell lysate containing c-Src protein was incubated with these beads for 3 to 4 hours at 4.degree. C. with rotation. At the end of the lysate incubation, the beads were rinsed three times in lysis buffer, resuspended in lysis buffer containing 10% glycerol, and frozen. These latex beads were thawed, rinsed three times in assay buffer (40 mM Tris, pH 7.5, 5 mM .mu.gCl.sub.2) and suspended in the same buffer. In a Millipore 96-well plate with a 0.65 .mu.m polyvinylidine membrane bottom were added the reaction components: 10 .mu.L c-Src beads, 10 .mu.L of 2.5 mg/mL poly GluTyr **substrate**, 5 .mu.M ATP containing 0.2 .mu.Ci labeled .sup.32 P-ATP, 5 .mu.L DMSO containing inhibitors or as a solvent control, and buff

ally have been shown to be bioavailable in animals, reaching peak plasma levels in nude mice in the range of about 10 nM to about 200 nM within 30 minutes following oral dosing at levels of about 4 to 5 mg/kg as suspensions in **lactate** buffer solutions having pH of 4.0. For example, the compound of Example 60 was administered orally at 5 mg/kg to mice, and plasma levels of about 200 nM were measured at 30 minutes following dosing. The compound was also administered intraperitoneally at 12 mg/kg and produced a peak plasma concentration of 10,000 nM at 30 minutes following dosing. When evaluated in female nude mice bearing subcutaneous MCF-7 human mammary tumor xenografts, the compound of Example 60 showed statistically insignificant tumor growth inhibitions at doses of 5 to 20 mg/kg when dosed on a schedule of q12 h.times.2; days 1-14.

The invention compounds can be formulated in conventional manners to provide convenient d

6506738

classes:1 514/80 1 514/25406 1 514/269 1 514/322 1 514/363 1 514/364 1 514/370 1 514/381 1 514/387 1 544/139 1 544/370 1 546/199 1 546/2737 1 548/113 1 548/139 1 548/132 1 548/181 1 548/250 1 548/3507 score: 355

keywords: water; co-solvent; ethanolamine; acetic acid; polyethylene; carbonate; ethyl acetate; acid methyl; acet ic acid; acetic; co-solvent; hydroxide; aqueous solution; formate; ethanol; alkyl; organic; fluoride; residue; claim ed; corresponding; sulfone; independently; hydroxylamine; hydrazine; solution; hydrogen; compounds; solvent; amine; ammonium; aqueous; oxide; acid; methyl; acetate; ethyl; nitrogen; hydroxyl; substituted; severe; ingredients; ambient; stirring; derivatives; magnesium; tartaric; hydrochloric acid; hydrochloric; surfactant; potassium; listed; dimet hyl; desirably; glycols; consists; amines; inhibit; dioxide; adding; fluorine; published; quaternary; phase; formulation; bath; isopropanol; formulations; aromatic; dissolving; completion; neutralized;

ure of compound 274 (6.4 g, 17.2 mmol), iron powder (2.89 g, 51.8 mmol) and ammonium chloride (4.61 g, 86.2 mmol) in MeOH (100 ml) and H.sub.2 O (100 ml) was heated to reflux for 4 h. The reaction mixture was filtered while hot through celite and the aqueous layer extracted with EtOAc. The **organic** layer was washed with brine, dried and evaporated. The **residue** was dissolved in CH.sub.3 CN (100 ml) and **acetic acid** (1 ml) and heated to reflux 4 h. The solvent was removed and the **residue** purified by flash chromatography eluting with hexanes-EtOAc (2:1 to 1:2) to yield 4.17 g (75%) of compound 274a as a viscous oil.

.sup.1 H NMR (CDC1.sub.3) .delta.1.86-1.98 (m, 2 H), 2.38-2.51 (m, 2 H), 3.34-3.39 (m, 1 H), 3.80-3.87 (m, 2 H), 4.06-4.14 (m, 1 H), 4.38-4.66 (m, 2 H), 7.18-7.19 (m, 1 H), 7.26-7.40 (m, 6 H), 7.72-7.74 (m, 1 H); MS m/e 372 (MH.sup.+). ##STR476##

To a solution of compound 274a (3.23 g, 10 mmol) in CH.sub.2 Cl.sub.2 at

4350606

classes:1 252/392 1 106/1415 1 106/1416 1 106/1442 1 252/364 1 422/16 1 510/255 1 510/266 1 510/499 1 516 /67 1 516/68 1 516/7 1 564/300 1 564/503 score: 351

keywords: water; N-methyl; alkyl; claimed; hydroxylamine; ratio; solution; compounds; amine; aqueous; metal; amines; novel; dioxide; adding; water-soluble; oxygen;

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classes:1 514/649 1 514/654 1 514/655 1 514/658 1 564/374 1 564/381 1 564/382 1 564/384 1 564/389 1 564/3 90 1 564/391 1 564/392 1 564/440

score: 337

keywords: water;dmso;dimethylsulfoxide;acetic acid;removing;polyethylene glycol;polyethylene;N-methyl;car bonate;propylene glycol;propylene;ethylene glycol;ethyl acetate;acetic acid;acetic;hydroxide;aqueous solu tion;ethanol;alkyl;organic;fluoride;residue;corresponding;sulfone;independently;dimethylsulfoxide;hydroxy lamine;hydrazine;ratio;solution;hydrogen;compounds;solvent;amine;ammonium;aqueous;metal;acid;methyl;aceta te;ethyl;ethylene;glycol;concentrations;carboxylic;ketone;beneficial;nitrogen;carbonyl;hydroxyl;functiona l groups;substituted;ingredients;blend;ambient;Stirring;derivatives;magnesium;benzoic;organic acids;hydrochloric acid;hydrochloric;phosphoric;sulfuric;zinc;potassium;amides;listed;dimethyl;desirably;discloses;a mmonia;amines;inhibit;novel;adding;fluorinated;solubility;European;published;quaternary ammonium;quaterna ry;ketones;phase;issued;formulation;temperatures;formulations;hydrocarbon;aromatic;phenolic;dissolving;co mpletion;acidic;neutralized;aluminum;oxygen;reacted;